

TLV237x 500 μ A/Ch、3MHz、レール・ツー・レール入力および出力 オペアンプ、シャットダウン搭載

1 特長

- レール・ツー・レール入出力
- 広い帯域幅: 3MHz
- 高いスルー・レート: 2.4V/ μ s
- 高い出力駆動能力: 105mA
- 電源電圧範囲: 2.7V~16V
- 消費電流: 550 μ A/チャンネル
- 低電力シャットダウン・モード
 - $I_{DD}(SHDN)$: 25 μ A/チャンネル
- 入力バイアス電流: 1pA
- 入力ノイズ電圧: 39nV/ $\sqrt{\text{Hz}}$
- ユニティ・ゲイン安定
- 規定温度範囲:
 - 40 $^{\circ}\text{C}$ ~+125 $^{\circ}\text{C}$ (産業用グレード)
- 超小型のパッケージ
 - 5または6ピンSOT-23 (TLV2370、TLV2371)
 - 8または10ピンVSSOP (TLV2372、TLV2373)

2 アプリケーション

- 白物家電
- ハンドヘルド・テスト機器
- 携帯用血糖値測定器
- リモート・センシング
- アクティブ・フィルタ
- 産業用オートメーション
- バッテリー駆動の電子機器

3 概要

TLV237x単一電源オペアンプには、レール・ツー・レール入力および出力機能があります。TLV237xは、最低2.7Vの電源電圧で動作し、拡張工業用温度範囲に対応し、レール・ツー・レール出力機能が追加されています。

TLV237xは、わずか550 μ Aの消費電流で、3MHzの帯域幅に対応します。推奨の最大電源電圧は16Vで、各種の充電可能セルにより動作できます($\pm 8\text{V}$ 電源から、最低 $\pm 1.35\text{V}$ まで)。

CMOS入力により、高インピーダンスのセンサ・インターフェイスを使用でき、低電圧での動作から、バッテリー駆動のアプリケーションにおいてTLC227xの代替品として理想的です。レール・ツー・レール入力段により、さらに多用途に使用可能です。TLV237xは、TIから続々と新製品が販売されているRRIOデバイスの7番目の製品で、最高16Vのレールから優れたAC性能で動作する最初の製品です。

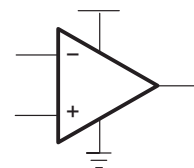
すべての製品がPDIPおよびSOICで供給され、シングルは小型のSOT-23パッケージ、デュアルはMSOP、クワッドはTSSOPパッケージで供給されます。TLV237xは2.7Vで動作するため、リチウムイオン・バッテリー駆動のシステムや、TIのMSP430など、現在利用可能な多くのMicropowerマイクロコントローラの動作電源電圧範囲と互換です。

製品情報⁽¹⁾

型番	パッケージ	本体サイズ(公称)
TLV237x	PDIP (8)	9.81mm×6.35mm
	PDIP (14)	19.30mm×6.35mm
	SOIC (8)	4.90mm×3.91mm
	SOIC (14)	8.65mm×3.91mm
	TSSOP (14)	5.00mm×4.40mm
	TSSOP (16)	
	SOT-23 (6)	2.90mm×1.60mm
	SOT-23 (5)	
	VSSOP (8)	3.00mm×3.00mm
	VSSOP (10)	

(1) 提供されているすべてのパッケージについては、データシートの末尾にある注文情報を参照してください。

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4 改訂履歴

Revision E (May 2016) から Revision F に変更 Page

- Changed names of pins 2 and 3 in TLV2372 D, DGK, and P packages pinout diagram 5

Revision D (January 2005) から Revision E に変更 Page

- 「ESD 定格」の表、「機能説明」セクション、「デバイスの機能モード」セクション、「アプリケーションと実装」セクション、「電源に関する推奨事項」セクション、「レイアウト」セクション、「デバイスおよびドキュメントのサポート」セクション、「メカニカル、パッケージ、および注文情報」セクションを追加 1
- Deleted TLV2370 and TLV2371 Available Options, TLV2372 AND TLV2373 Available Options, and TLV2374 and TLV2375 Available Options tables 3
- Deleted Continuous total power dissipation and lead temperature specifications from Absolute Maximum Ratings table ... 9
- Deleted Dissipation Ratings table 17

5 Device Comparison Tables

Table 1. Selection of Signal Amplifier Products⁽¹⁾

DEVICE	V _{DD} (V)	V _{IO} (μ V)	I _O /Ch (μ A)	I _{IB} (pA)	GBW (MHz)	SR (V/ μ s)	SHUTDOWN	RAIL-TO-RAIL	SINGLES, DUALS, QUADS
TLV237x	2.7 to 16	500	550	1	3	2.4	Yes	I/O	S, D, Q
TLC227x	4 to 16	300	1100	1	2.2	3.6	—	O	D, Q
TLV27x	2.7 to 16	500	550	1	3	2.4	—	O	S, D, Q
TLC27x	3 to 16	1100	675	1	1.7	3.6	—	—	S, D, Q
TLV246x	2.7 to 16	150	550	1300	6.4	1.6	Yes	I/O	S, D, Q
TLV247x	2.7 to 16	250	600	2	2.8	1.5	Yes	I/O	S, D, Q
TLV244x	2.7 to 10	300	725	1	1.8	1.4	—	O	D, Q

(1) Typical values measured at 5 V and 25°C.

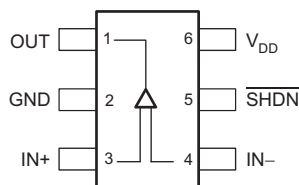
Table 2. Family Package Table⁽¹⁾

DEVICE	NUMBER OF CHANNELS	PACKAGE TYPES					SHUTDOWN	UNIVERSAL EVM BOARD
		PDIP	SOIC	SOT-23	TSSOP	MSOP		
TLV2370	1	8	8	6	—	—	Yes	See the EVM Selection Guide
TLV2371	1	8	8	5	—	—	—	
TLV2372	2	8	8	—	—	8	—	
TLV2373	2	14	14	—	—	10	Yes	
TLV2374	4	14	14	—	14	—	—	
TLV2375	4	16	16	—	16	—	Yes	

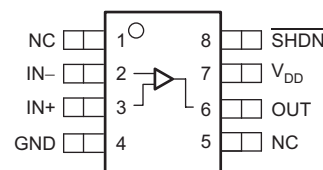
(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

6 Pin Configuration and Functions

**TLV2370 DBV Package
6-Pin SOT-23
Top View**



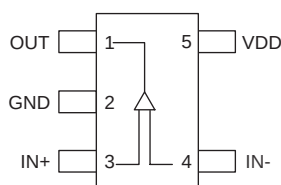
**TLV2370 D and P Packages
8-Pin SOIC and PDIP
Top View**



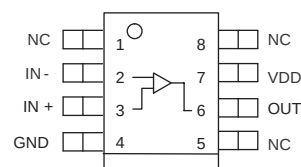
Pin Functions: TLV2370

PIN			I/O	DESCRIPTION
NAME	SOT-23	SOIC, PDIP		
GND	2	4	—	Ground connection
IN–	4	2	I	Negative (inverting) input
IN+	3	3	I	Positive (noninverting) input
NC	—	1, 5	—	No internal connection (can be left floating)
OUT	1	6	O	Output
SHDN	5	8	I	Shutdown control (active low, can be left floating)
V _{DD}	6	7	—	Positive power supply

**TLV2371 DBV Package
5-Pin SOT-23
Top View**



**TLV2371 D and P Packages
8-Pin SOIC and PDIP
Top View**

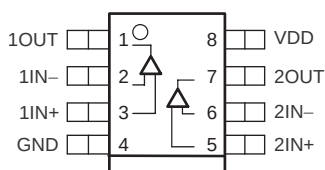


NC- no internal connection

Pin Functions: TLV2371

PIN			I/O	DESCRIPTION
NAME	SOT-23	SOIC, PDIP		
GND	2	4	—	Ground connection
IN–	4	2	I	Negative (inverting) input
IN+	3	3	I	Positive (noninverting) input
NC	—	1, 5, 8	—	No internal connection (can be left floating)
OUT	1	6	O	Output
V _{DD}	5	7	—	Positive power supply

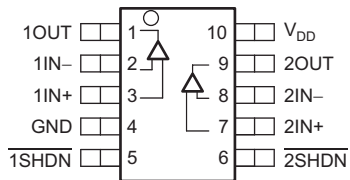
**TLV2372 D, DGK, and P Packages
8-Pin SOIC, VSSOP, and PDIP
Top View**



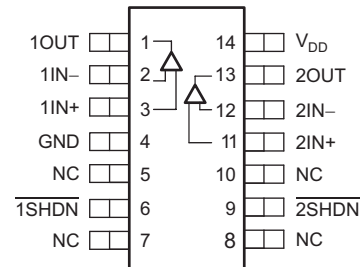
Pin Functions: TLV2372

PIN		I/O	DESCRIPTION
NAME	SOIC, VSSOP, PDIP		
GND	4	—	Ground connection
1IN–	2	I	Inverting input, channel 1
1IN+	3	I	Noninverting input, channel 1
2IN–	6	I	Inverting input, channel 2
2IN+	5	I	Noninverting input, channel 2
1OUT	1	O	Output, channel 1
2OUT	7	O	Output, channel 2
V _{DD}	8	—	Positive power supply

**TLV2373 DGS Package
10-Pin VSSOP
Top View**



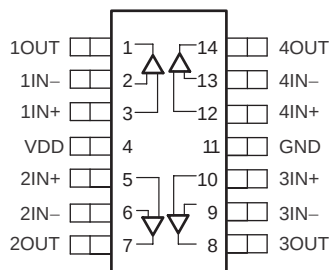
**TLV2373 D and N Packages
14-Pin SOIC and PDIP
Top View**



Pin Functions: TLV2373

PIN			I/O	DESCRIPTION
NAME	SOIC, PDIP	VSSOP		
GND	4	4	—	Ground connection
1IN–	2	2	I	Inverting input, channel 1
1IN+	3	3	I	Noninverting input, channel 1
2IN–	12	8	I	Inverting input, channel 2
2IN+	11	7	I	Noninverting input, channel 2
1OUT	1	1	O	Output, channel 1
2OUT	13	9	O	Output, channel 2
1SHDN	6	5	I	Shutdown control, channel 1, (active low, can be left floating)
2SHDN	9	6	I	Shutdown control, channel 2, (active low, can be left floating)
V _{DD}	14	10	—	Positive power supply
NC	5, 7, 8, 10	—	—	No internal connection (can be left floating)

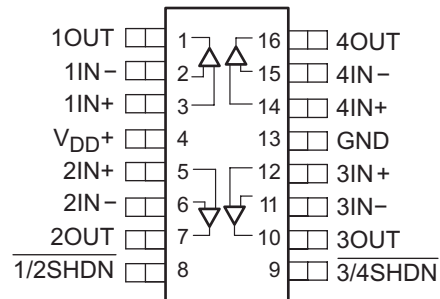
**TLV2374 D, N, and PW Packages
14-Pin SOIC, PDIP, and TSSOP
Top View**



Pin Functions: TLV2374

PIN		I/O	DESCRIPTION
NAME	SOIC, PDIP, TSSOP		
GND	11	—	Ground connection
1IN-	2	I	Inverting input, channel 1
1IN+	3	I	Noninverting input, channel 1
2IN-	6	I	Inverting input, channel 2
2IN+	5	I	Noninverting input, channel 2
3IN-	9	I	Inverting input, channel 3
3IN+	10	I	Noninverting input, channel 3
4IN-	13	I	Inverting input, channel 4
4IN+	12	I	Noninverting input, channel 4
1OUT	1	O	Output, channel 1
2OUT	7	O	Output, channel 2
3OUT	8	O	Output, channel 3
4OUT	14	O	Output, channel 4
V _{DD}	4	—	Positive power supply

**TLV2375 D, N, and PW Packages
16-Pin SOIC, PDIP, and TSSOP
Top View**



Pin Functions: TLV2375

PIN		I/O	DESCRIPTION
NAME	SOIC, PDIP, TSSOP		
GND	13	—	Ground connection
1IN-	2	I	Inverting input, channel 1
2IN-	6	I	Inverting input, channel 2
3IN-	11	I	Inverting input, channel 3
4IN-	15	I	Inverting input, channel 4
1IN+	3	I	Noninverting input, channel 1
2IN+	5	I	Noninverting input, channel 2
3IN+	12	I	Noninverting input, channel 3
4IN+	14	I	Noninverting input, channel 4
1OUT	1	O	Output, channel 1
2OUT	7	O	Output, channel 2
3OUT	10	O	Output, channel 3
4OUT	16	O	Output, channel 4
1/2SHDN	8	I	Shutdown control, channels 1 and 2, (active low, can be left floating)
3/4SHDN	9	I	Shutdown control, channels 3 and 4, (active low, can be left floating)
VDD	4	—	Positive power supply

7 Specifications

7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
Voltage	Supply voltage, V_{DD} ⁽²⁾		16.5	V
	Differential input voltage, V_{ID}	$-V_{DD}$	V_{DD}	
	Input voltage, V_I ⁽²⁾	-0.2	$V_{DD} + 0.2$	
Current	Input current, I_{IN}	-10	10	mA
	Output current, I_O	-100	100	
Temperature	Operating free-air temperature, T_A : I-suffix	-40	125	°C
	Maximum junction temperature, T_J		150	
	Storage temperature, T_{stg}	-65	150	

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values, except differential voltages, are with respect to GND.

7.2 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted).

		MIN	MAX	UNIT
Supply voltage, V_{DD}	Single supply	2.7	16	V
	Split supply	± 1.35	± 8	
Common-mode input voltage, V_{CM}		0	V_{DD}	V
Operating free-air temperature, T_A	I-suffix	-40	125	°C
Turnon voltage (shutdown pin voltage level), $V_{(ON)}$, relative to GND pin voltage			2	V
Turnoff (shutdown pin voltage level), $V_{(OFF)}$, relative to GND pin voltage		0.8		V

7.3 Thermal Information: TLV2370

THERMAL METRIC ⁽¹⁾		TLV2370			UNIT
		DBV (SOT-23)	D (SOIC)	P (PDIP)	
		6 PINS	8 PINS	8 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	228.5	138.4	49.2	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	99.1	89.5	39.4	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	54.6	78.6	26.4	°C/W
ψ_{JT}	Junction-to-top characterization parameter	7.7	29.9	15.4	°C/W
ψ_{JB}	Junction-to-board characterization parameter	53.8	78.1	26.3	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	n/a	n/a	n/a	°C/W

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

7.4 Thermal Information: TLV2371

THERMAL METRIC ⁽¹⁾		TLV2371			UNIT
		DBV (SOT-23)	D (SOIC)	P (PDIP)	
		5 PINS	8 PINS	8 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	228.5	138.4	49.2	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	99.1	89.5	39.4	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	54.6	78.6	26.4	°C/W
ψ_{JT}	Junction-to-top characterization parameter	7.7	29.9	15.4	°C/W
ψ_{JB}	Junction-to-board characterization parameter	53.8	78.1	26.3	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	n/a	n/a	n/a	°C/W

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

7.5 Thermal Information: TLV2372

THERMAL METRIC ⁽¹⁾		TLV2372			UNIT
		D (SOIC)	DGK (VSSOP)	P (PDIP)	
		8 PINS	8 PINS	8 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	138.4	191.2	49.2	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	89.5	61.9	39.4	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	78.6	111.9	26.4	°C/W
ψ_{JT}	Junction-to-top characterization parameter	29.9	5.1	15.4	°C/W
ψ_{JB}	Junction-to-board characterization parameter	78.1	110.2	26.3	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	n/a	n/a	n/a	°C/W

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

7.6 Thermal Information: TLV2373

THERMAL METRIC ⁽¹⁾		TLV2373			UNIT
		DGS (VSSOP)	D (SOIC)	P (PDIP)	
		10 PINS	14 PINS	14 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	166.5	67	66.3	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	41.8	24.1	20.5	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	86.1	22.5	26.8	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	1.5	2.2	2.1	°C/W
Ψ_{JB}	Junction-to-board characterization parameter	84.7	22.1	26.2	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	n/a	n/a	n/a	°C/W

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

7.7 Thermal Information: TLV2374

THERMAL METRIC ⁽¹⁾		TLV2374			UNIT
		D (SOIC)	N (PDIP)	PW (TSSOP)	
		14 PINS	14 PINS	14 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	67	66.3	121	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	24.1	20.5	49.4	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	22.5	26.8	62.8	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	2.2	2.1	5.9	°C/W
Ψ_{JB}	Junction-to-board characterization parameter	22.1	26.2	62.2	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	n/a	n/a	n/a	°C/W

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

7.8 Thermal Information: TLV2375

THERMAL METRIC ⁽¹⁾		TLV2375			UNIT
		D (SOIC)	N (PDIP)	PW (TSSOP)	
		16 PINS	16 PINS	16 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	83	55.8	115.6	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	44	43.1	50.5	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	40.5	35.8	60.7	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	11.5	27.9	7.4	°C/W
Ψ_{JB}	Junction-to-board characterization parameter	40.2	35.7	60.1	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	n/a	n/a	n/a	°C/W

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

7.9 Electrical Characteristics

at $T_A = 25^\circ\text{C}$, $V_{DD} = 2.7\text{ V}$, 5 V , and 15 V (unless otherwise noted).

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT	
DC PERFORMANCE								
V _{OS}	Input offset voltage	At T _A = 25°C, V _{IC} = V _{DD} /2, V _O = V _{DD} /2, R _S = 50 Ω			2	4.5	mV	
		At T _A = −40°C to +125°C, V _{IC} = V _{DD} /2, V _O = V _{DD} /2, R _S = 50 Ω				6	mV	
dV _{OS} /dT	Offset voltage drift	At T _A = 25°C, V _{IC} = V _{DD} /2, V _O = V _{DD} /2, R _S = 50 Ω			2		μV/°C	
CMRR	Common-mode rejection ratio	V _{DD} = 2.7 V, R _S = 50 Ω	V _{IC} = 0 to V _{DD}	50	68		dB	
			At T _A = −40°C to +125°C, V _{IC} = 0 to V _{DD}	49				
			V _{IC} = 0 to V _{DD} − 1.35 V	56	70			
			At T _A = −40°C to +125°C, V _{IC} = 0 to V _{DD} − 1.35 V	54				
		V _{DD} = 5 V, R _S = 50 Ω	V _{IC} = 0 to V _{DD}	55	72			
			At T _A = −40°C to +125°C, V _{IC} = 0 to V _{DD}	54				
			V _{IC} = 0 to V _{DD} − 1.35 V	67	80			
			At T _A = −40°C to +125°C, V _{IC} = 0 to V _{DD} − 1.35 V	64				
		V _{DD} = 15 V, R _S = 50 Ω	V _{IC} = 0 to V _{DD}	64	82			
			At T _A = −40°C to +125°C, V _{IC} = 0 to V _{DD}	63				
			V _{IC} = 0 to V _{DD} − 1.35 V	67	84			
			At T _A = −40°C to +125°C, V _{IC} = 0 to V _{DD} − 1.35 V	66				
A _{VD}	Large-signal differential voltage amplification	V _{DD} = 2.7 V, V _{O(PP)} = V _{DD} /2, R _L = 10 kΩ		98	106		dB	
			At T _A = −40°C to +125°C	76				
		V _{DD} = 5 V, V _{O(PP)} = V _{DD} /2, R _L = 10 kΩ		100	110			
			At T _A = −40°C to +125°C	86				
		V _{DD} = 15 V, V _{O(PP)} = V _{DD} /2, R _L = 10 kΩ		81	83			
			At T _A = −40°C to +125°C	79				
INPUT CHARACTERISTICS								
I _{OS}	Input offset current	V _{DD} = 15 V, V _{IC} = V _O = V _{DD} /2			1	60	pA	
			At T _A = 70°C			100		
			At T _A = 125°C			1000		
I _B	Input bias current	V _{DD} = 15 V, V _{IC} = V _O = V _{DD} /2			1	60	pA	
			At T _A = 70°C			100		
			At T _A = 125°C			1000		
	Differential input resistance				1000		GΩ	
	Common-mode input capacitance	f = 21 kHz			8		pF	

Electrical Characteristics (continued)

at $T_A = 25^\circ\text{C}$, $V_{DD} = 2.7\text{ V}$, 5 V , and 15 V (unless otherwise noted).

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OUTPUT CHARACTERISTICS					

Electrical Characteristics (continued)

at $T_A = 25^\circ\text{C}$, $V_{DD} = 2.7\text{ V}$, 5 V , and 15 V (unless otherwise noted).

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{OH}	High-level output voltage	$V_{DD} = 2.7\text{ V}$ At $T_A = 25^\circ\text{C}$, $V_{IC} = V_{DD}/2$, $I_{OH} = -1\text{ mA}$	2.55	2.58		
		At $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$, $V_{IC} = V_{DD}/2$, $I_{OH} = -1\text{ mA}$	2.48			
		$V_{DD} = 5\text{ V}$ At $T_A = 25^\circ\text{C}$, $V_{IC} = V_{DD}/2$, $I_{OH} = -1\text{ mA}$	4.9	4.93		
		At $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$, $V_{IC} = V_{DD}/2$, $I_{OH} = -1\text{ mA}$	4.85			
		$V_{DD} = 15\text{ V}$ At $T_A = 25^\circ\text{C}$, $V_{IC} = V_{DD}/2$, $I_{OH} = -1\text{ mA}$	14.92	14.96		
		At $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$, $V_{IC} = V_{DD}/2$, $I_{OH} = -1\text{ mA}$	14.9			
		At $T_A = 25^\circ\text{C}$, $V_{IC} = V_{DD}/2$, $I_{OH} = -5\text{ mA}$	1.9	2		V
		$V_{DD} = 2.7\text{ V}$ At $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$, $V_{IC} = V_{DD}/2$, $I_{OH} = -5\text{ mA}$	1.6			
		$V_{DD} = 5\text{ V}$ At $T_A = 25^\circ\text{C}$, $V_{IC} = V_{DD}/2$, $I_{OH} = -5\text{ mA}$	4.6	4.68		
		At $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$, $V_{IC} = V_{DD}/2$, $I_{OH} = -5\text{ mA}$	4.5			
		$V_{DD} = 15\text{ V}$ At $T_A = 25^\circ\text{C}$, $V_{IC} = V_{DD}/2$, $I_{OH} = -5\text{ mA}$	14.7	14.8		
		At $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$, $V_{IC} = V_{DD}/2$, $I_{OH} = -5\text{ mA}$	14.6			
V_{OL}	Low-level output voltage	$V_{DD} = 2.7\text{ V}$ At $T_A = 25^\circ\text{C}$, $V_{IC} = V_{DD}/2$, $I_{OL} = 1\text{ mA}$		0.1	0.15	
		At $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$, $V_{IC} = V_{DD}/2$, $I_{OL} = 1\text{ mA}$			0.22	
		$V_{DD} = 5\text{ V}$ At $T_A = 25^\circ\text{C}$, $V_{IC} = V_{DD}/2$, $I_{OL} = 1\text{ mA}$		0.05	0.1	
		At $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$, $V_{IC} = V_{DD}/2$, $I_{OL} = 1\text{ mA}$			0.15	
		$V_{DD} = 15\text{ V}$ At $T_A = 25^\circ\text{C}$, $V_{IC} = V_{DD}/2$, $I_{OL} = 1\text{ mA}$		0.05	0.08	
		At $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$, $V_{IC} = V_{DD}/2$, $I_{OL} = 1\text{ mA}$			0.1	
		$V_{DD} = 2.7\text{ V}$ At $T_A = 25^\circ\text{C}$, $V_{IC} = V_{DD}/2$, $I_{OL} = 5\text{ mA}$		0.52	0.7	V
		At $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$, $V_{IC} = V_{DD}/2$, $I_{OL} = 5\text{ mA}$			1.1	
		$V_{DD} = 5\text{ V}$ At $T_A = 25^\circ\text{C}$, $V_{IC} = V_{DD}/2$, $I_{OL} = 5\text{ mA}$		0.28	0.4	
		At $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$, $V_{IC} = V_{DD}/2$, $I_{OL} = 5\text{ mA}$			0.5	

 TEXAS INSTRUMENTS			TLV2370, TLV2371, TLV2372 TLV2373, TLV2374, TLV2375			
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Electrical Characteristics (continued)						
at T _A = 25°C, V _{DD} = 2.7 V, 5 V, and 15 V (unless otherwise noted):		At T _A = 25°C, V _{IC} = V _{DD} /2, I _{OL} = 5 mA				
PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT
	V _{DD} = 15 V	At T _A = –40°C to +125°C, V _{IC} = V _{DD} /2, I _{OL} = 5 mA			0.35	
I _O Output current	V _{DD} = 2.7 V, V _O = 0.5 V from rail	Positive rail		4		mA
		Negative rail		5		
	V _{DD} = 5 V, V _O = 0.5 V from rail	Positive rail		7		
		Negative rail		8		
	V _{DD} = 15 V, V _O = 0.5 V from rail	Positive rail		16		
		Negative rail		15		

Electrical Characteristics (continued)

at $T_A = 25^\circ\text{C}$, $V_{DD} = 2.7\text{ V}$, 5 V , and 15 V (unless otherwise noted).

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
POWER SUPPLY							
I _{DD}	Supply current (per channel)	V _{DD} = 2.7 V, V _O = V _{DD} /2			470	560	μA
		V _{DD} = 5 V, V _O = V _{DD} /2			550	660	
		V _{DD} = 15 V, V _O = V _{DD} /2	At T _A = 25°C		750	900	
			At T _A = −40°C to +125°C			1200	
PSRR	Power-supply rejection ratio (ΔV _{DD} /ΔV _{IO})	V _{DD} = 2.7 V to 15 V, V _{IC} = V _{DD} /2, no load	At T _A = 25°C	70	80		dB
			At T _A = −40°C to +125°C	65			
DYNAMIC PERFORMANCE							
UGBW	Unity gain bandwidth	V _{DD} = 2.7 V	R _L = 2 kΩ, C _L = 10 pF		2.4		MHz
		V _{DD} = 5 V to 15 V	R _L = 2 kΩ, C _L = 10 pF		3		
SR	Slew rate at unity gain	V _{DD} = 2.7 V	At T _A = 25°C, V _{O(PP)} = V _{DD} /2, C _L = 50 pF, R _L = 10 kΩ	1.4	2		V/μs
			At T _A = −40°C to +125°C, V _{O(PP)} = V _{DD} /2, C _L = 50 pF, R _L = 10 kΩ	1			
		V _{DD} = 5 V	At T _A = 25°C, V _{O(PP)} = V _{DD} /2, C _L = 50 pF, R _L = 10 kΩ	1.6	2.4		
			At T _A = −40°C to +125°C, V _{O(PP)} = V _{DD} /2, C _L = 50 pF, R _L = 10 kΩ	1.2			
		V _{DD} = 15 V	At T _A = 25°C, V _{O(PP)} = V _{DD} /2, C _L = 50 pF, R _L = 10 kΩ	1.9	2.1		
			At T _A = −40°C to +125°C, V _{O(PP)} = V _{DD} /2, C _L = 50 pF, R _L = 10 kΩ	1.4			
φ _m	Phase margin	R _L = 2 kΩ, C _L = 100 pF			65		°
	Gain margin	R _L = 2 kΩ, C _L = 10 pF			18		dB
t _s	Settling time	V _{DD} = 2.7 V, V _{(STEP)PP} = 1 V, A _V = −1, C _L = 10 pF, R _L = 2 kΩ, 0.1%			2.9		μs
		V _{DD} = 5 V, 15 V, V _{(STEP)PP} = 1 V, A _V = −1, C _L = 47 pF, R _L = 2 kΩ, 0.1%			2		

Electrical Characteristics (continued)

at $T_A = 25^\circ\text{C}$, $V_{DD} = 2.7\text{ V}$, 5 V , and 15 V (unless otherwise noted).

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
NOISE, DISTORTION PERFORMANCE						
THD + N	Total harmonic distortion plus noise	$V_{DD} = 2.7\text{ V}$	$V_{O(PP)} = V_{DD}/2\text{ V}$, $R_L = 2\text{ k}\Omega$, $f = 10\text{ kHz}$, $A_V = 1$	0.02%		
			$V_{O(PP)} = V_{DD}/2\text{ V}$, $R_L = 2\text{ k}\Omega$, $f = 10\text{ kHz}$, $A_V = 10$	0.05%		
			$V_{O(PP)} = V_{DD}/2\text{ V}$, $R_L = 2\text{ k}\Omega$, $f = 10\text{ kHz}$, $A_V = 100$	0.18%		
		$V_{DD} = 5\text{ V}$, 15 V	$V_{O(PP)} = V_{DD}/2\text{ V}$, $R_L = 2\text{ k}\Omega$, $f = 10\text{ kHz}$, $A_V = 1$	0.02%		
			$V_{O(PP)} = V_{DD}/2\text{ V}$, $R_L = 2\text{ k}\Omega$, $f = 10\text{ kHz}$, $A_V = 10$	0.09%		
			$V_{O(PP)} = V_{DD}/2\text{ V}$, $R_L = 2\text{ k}\Omega$, $f = 10\text{ kHz}$, $A_V = 100$	0.5%		
V_n	Equivalent input noise voltage	$f = 1\text{ kHz}$		39		$\text{nV}/\sqrt{\text{Hz}}$
		$f = 10\text{ kHz}$		35		
I_n	Equivalent input noise current	$f = 1\text{ kHz}$		0.6		$\text{fA}/\sqrt{\text{Hz}}$
SHUTDOWN CHARACTERISTICS						
$I_{DD(\text{SHDN})}$	Supply current in shutdown mode (TLV2370, TLV2373, TLV2375) (per channel)	$V_{DD} = 2.7\text{ V}$, 5 V , $\text{SHDN} = 0\text{ V}$	At $T_A = 25^\circ\text{C}$	25	30	μA
			At $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$		35	
		$V_{DD} = 15\text{ V}$, $\text{SHDN} = 0\text{ V}$	At $T_A = 25^\circ\text{C}$	40	45	
			At $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$		50	
$t_{\text{(on)}}$	Amplifier turnon time ⁽¹⁾	$R_L = 2\text{ k}\Omega$		0.8		μs
$t_{\text{(off)}}$	Amplifier turnoff time ⁽¹⁾	$R_L = 2\text{ k}\Omega$		1		μs

(1) Disable time and enable time are defined as the interval between application of the logic signal to the SHDN terminal and the point at which the supply current has reached one half of its final value.

8 Typical Characteristics

Table 3. Table of Graphs

			FIGURE
V_{IO}	Input offset voltage	vs Common-mode input voltage	Figure 1, Figure 2, Figure 3
CMRR	Common-mode rejection ratio	vs Frequency	Figure 4
	Input bias and offset current	vs Free-air temperature	Figure 5
V_{OL}	Low-level output voltage	vs Low-level output current	Figure 6, Figure 8, Figure 10
V_{OH}	High-level output voltage	vs High-level output current	Figure 7, Figure 9, Figure 11
$V_{O(PP)}$	Peak-to-peak output voltage	vs Frequency	Figure 12
I_{DD}	Supply current	vs Supply voltage	Figure 13
PSRR	Power supply rejection ratio	vs Frequency	Figure 14
A_{VD}	Differential voltage gain and phase	vs Frequency	Figure 15
	Gain-bandwidth product	vs Free-air temperature	Figure 16
SR	Slew rate	vs Supply voltage	Figure 17
		vs Free-air temperature	Figure 18
ϕ_m	Phase margin	vs Capacitive load	Figure 19
V_n	Equivalent input noise voltage	vs Frequency	Figure 20
	Voltage-follower large-signal pulse response		Figure 21, Figure 22
	Voltage-follower small-signal pulse response		Figure 23
	Inverting large-signal response		Figure 24, Figure 25
	Inverting small-signal response		Figure 26
	Crosstalk	vs Frequency	Figure 27
	Shutdown forward & reverse isolation	vs Frequency	Figure 28
$I_{DD(SHDN)}$	Shutdown supply current	vs Supply voltage	Figure 29
$I_{DD(SHDN)}$	Shutdown pin leakage current	vs Shutdown pin voltage	Figure 30
$I_{DD(SHDN)}$	Shutdown supply current, output voltage	vs Time	Figure 31, Figure 32

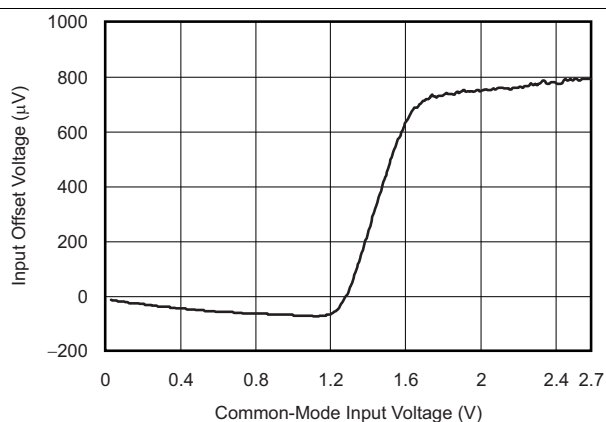


Figure 1. Input Offset Voltage vs Common-Mode Input Voltage

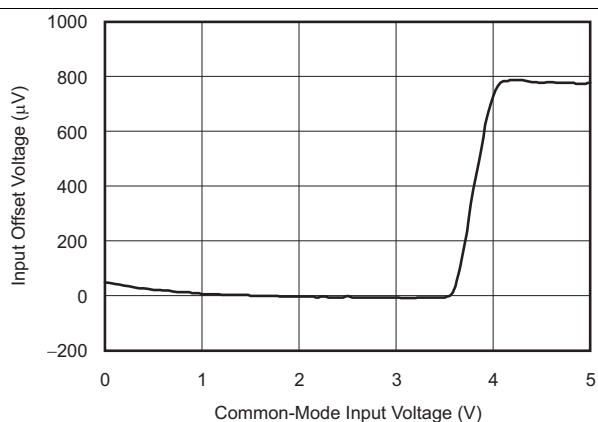


Figure 2. Input Offset Voltage vs Common-Mode Input Voltage

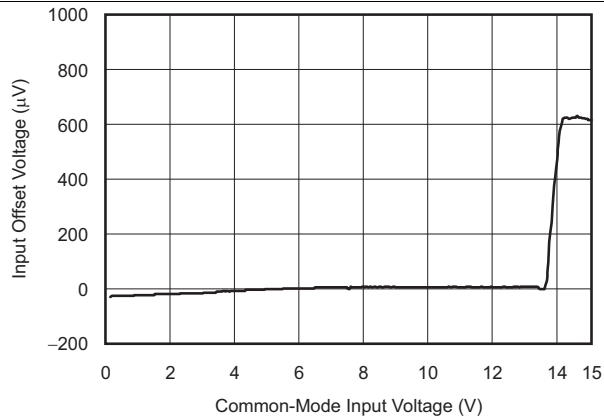


Figure 3. Input Offset Voltage vs Common-Mode Input Voltage

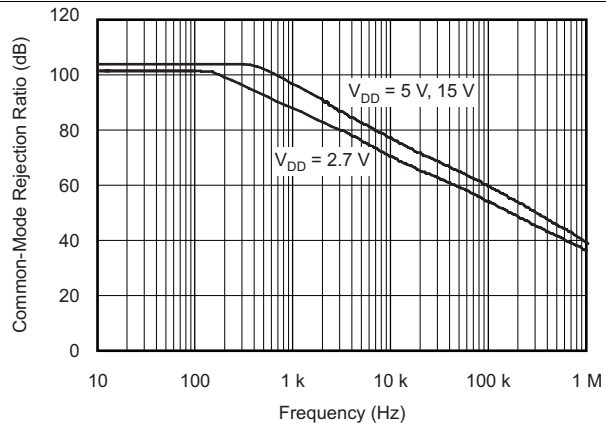


Figure 4. Common-Mode Rejection Ratio vs Frequency

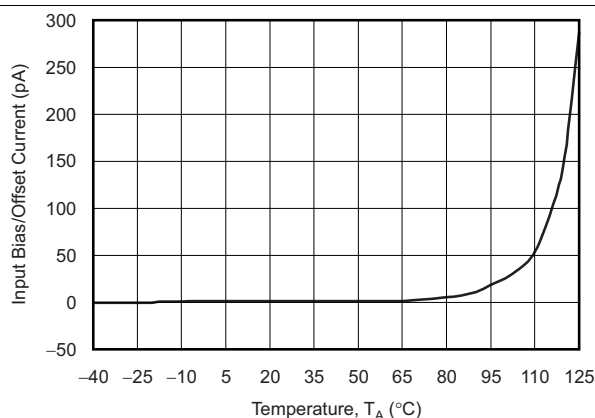


Figure 5. Input Bias or Offset Current vs Free-Air Temperature

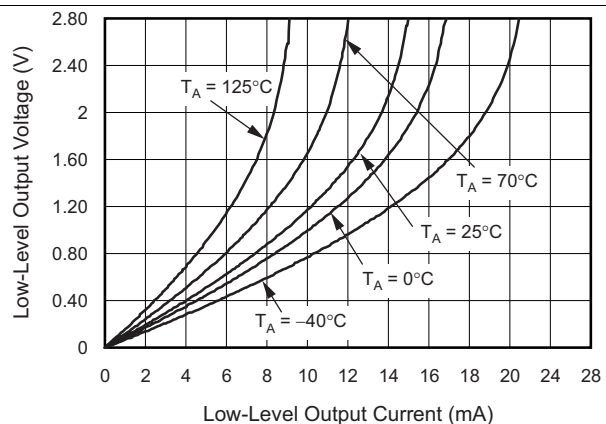


Figure 6. Low-Level Output Voltage vs Low-Level Output Current

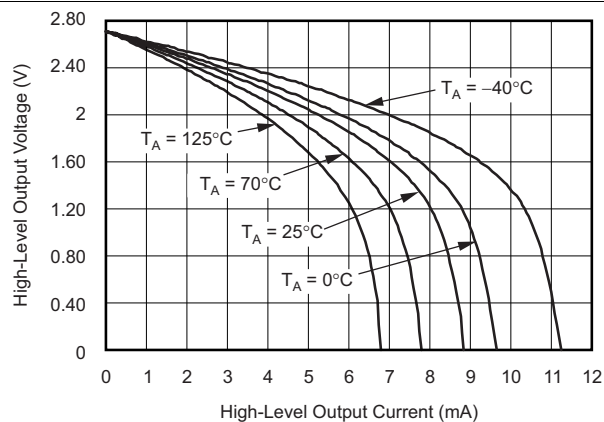


Figure 7. High-Level Output Voltage vs High-Level Output Current

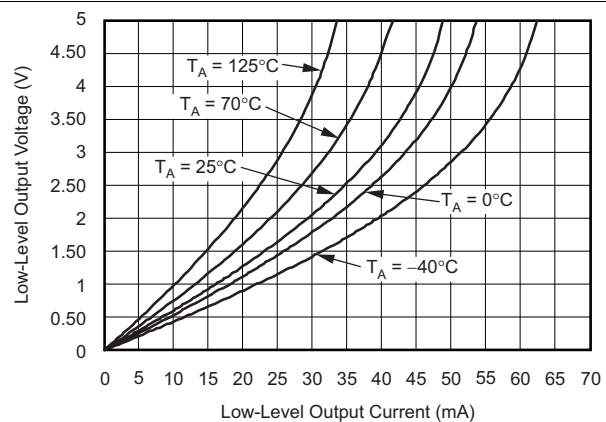


Figure 8. Low-Level Output Voltage vs Low-Level Output Current

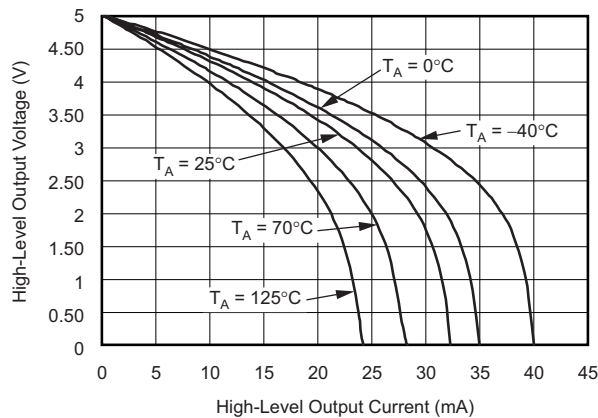


Figure 9. High-Level Output Voltage vs High-Level Output Current

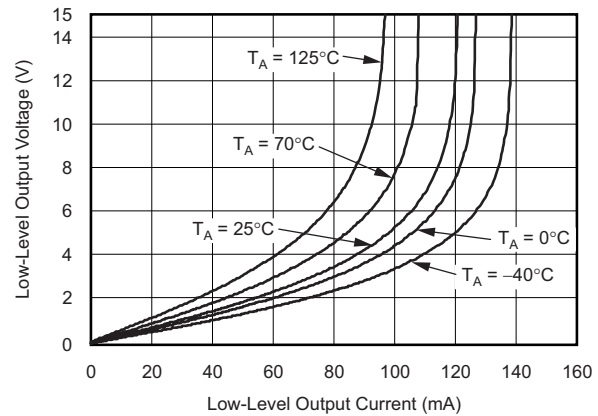


Figure 10. Low-Level Output Voltage vs Low-Level Output Current

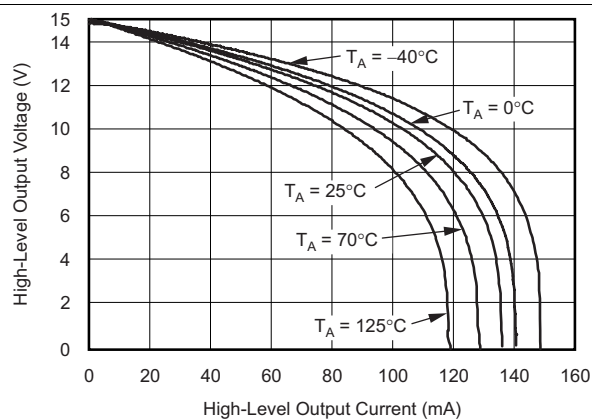


Figure 11. High-Level Output Voltage vs High-Level Output Current

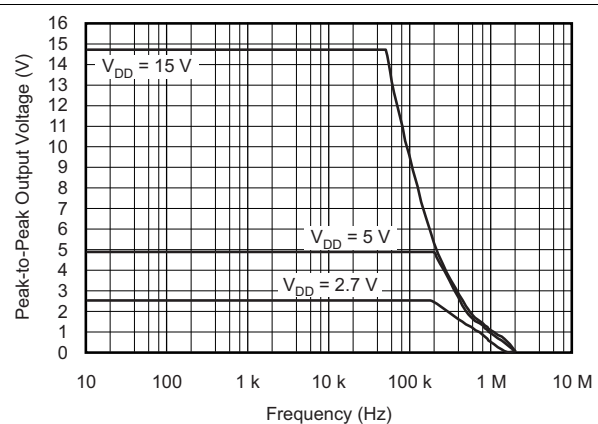


Figure 12. Peak-to-Peak Output Voltage vs Frequency

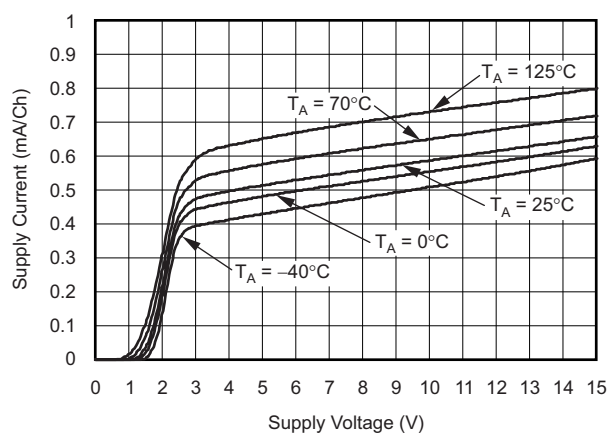


Figure 13. Supply Current vs Supply Voltage

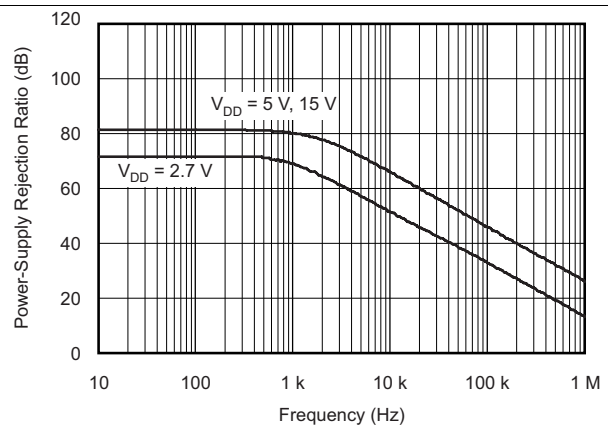


Figure 14. Power Supply Rejection Ratio vs Frequency

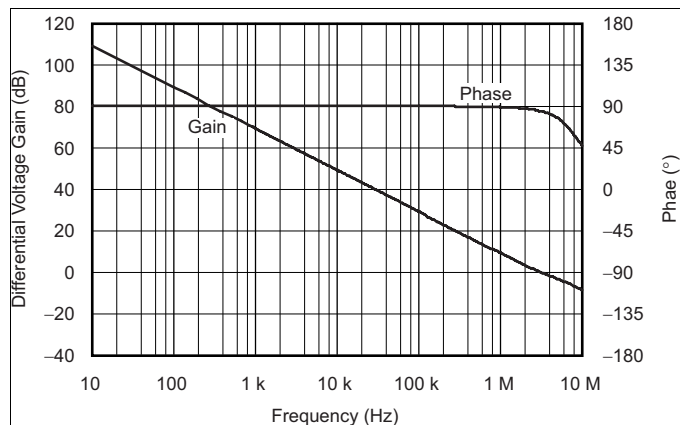


Figure 15. Differential Voltage Gain and Phase vs Frequency



Figure 16. Gain Bandwidth Product vs Free-Air Temperature

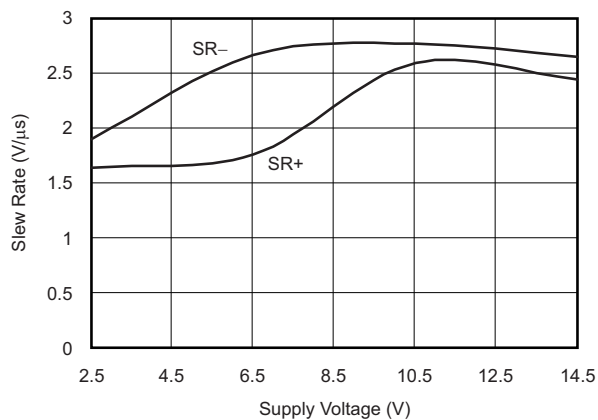


Figure 17. Slew Rate vs Supply Voltage

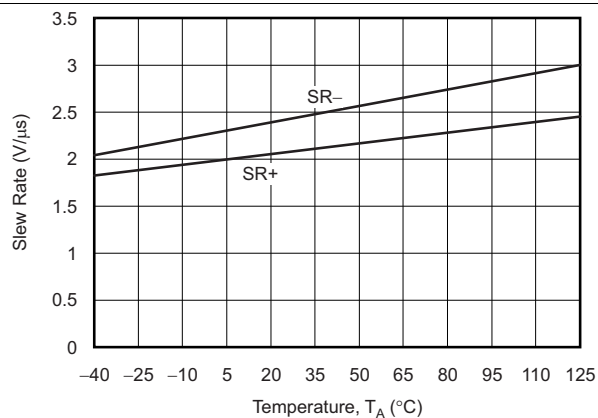


Figure 18. Slew Rate vs Free-Air Temperature

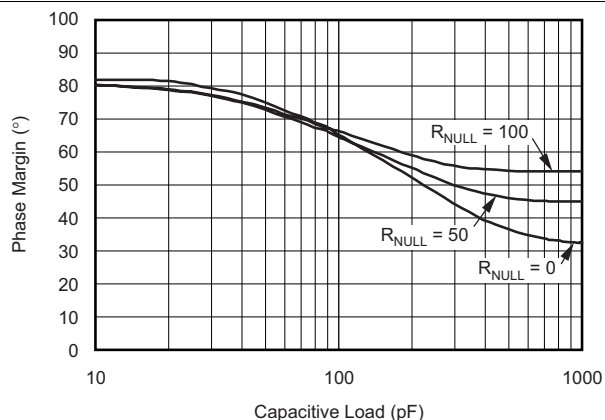


Figure 19. Phase Margin vs Capacitive Load

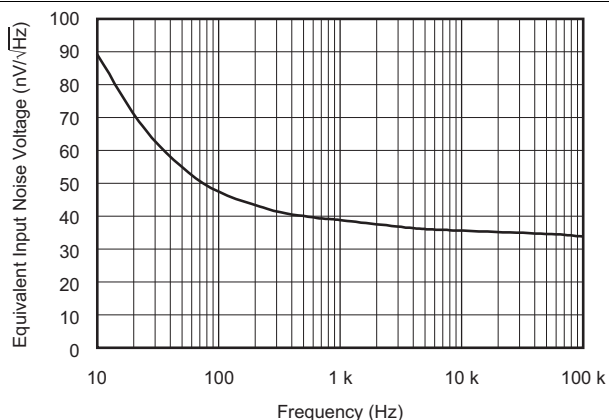


Figure 20. Equivalent Input Noise Voltage vs Frequency

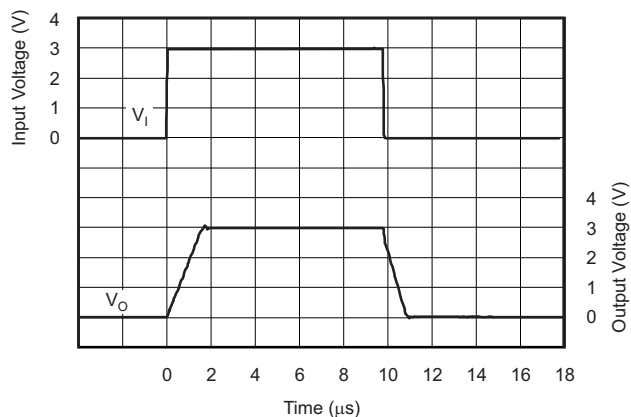


Figure 21. Voltage-Follower Large-Signal Pulse Response

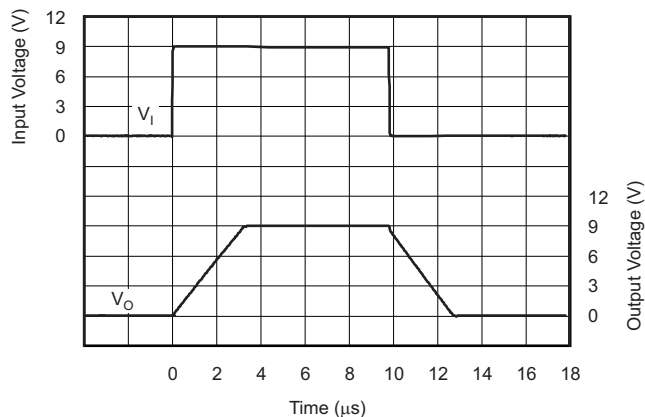


Figure 22. Voltage-Follower Large-Signal Pulse Response

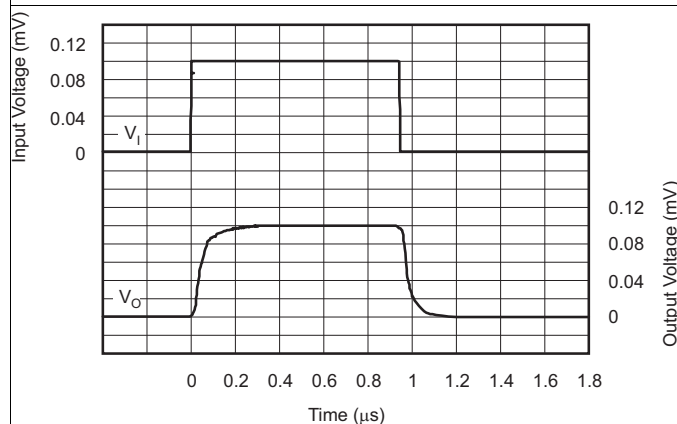


Figure 23. Voltage-Follower Small-Signal Pulse Response

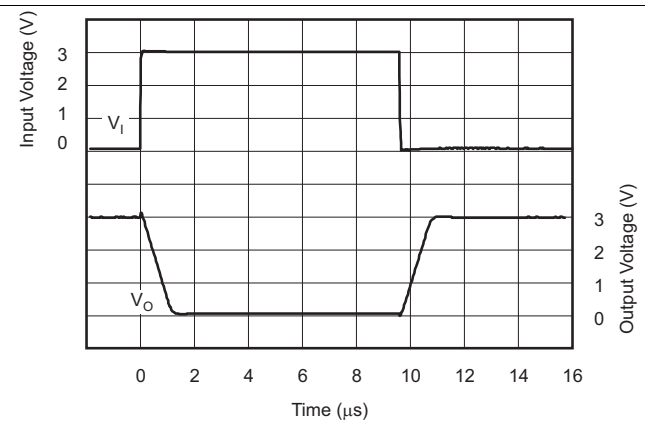


Figure 24. Inverting Large-Signal Response

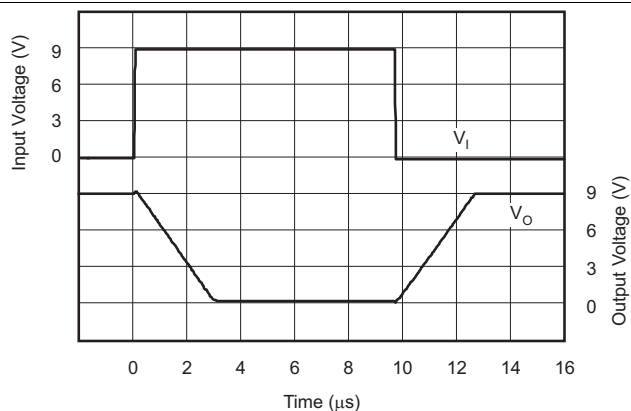


Figure 25. Inverting Large-Signal Response

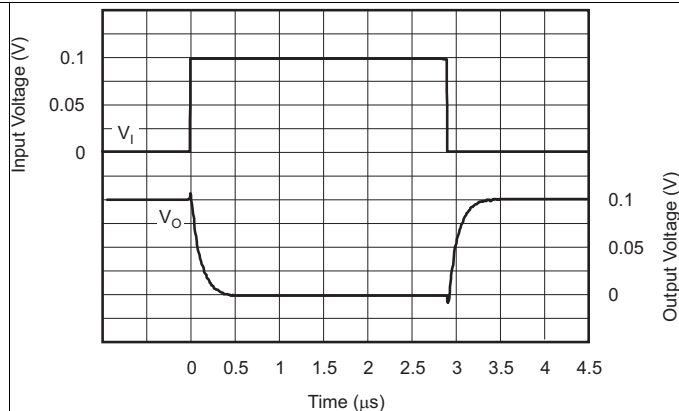


Figure 26. Inverting Small-Signal Response

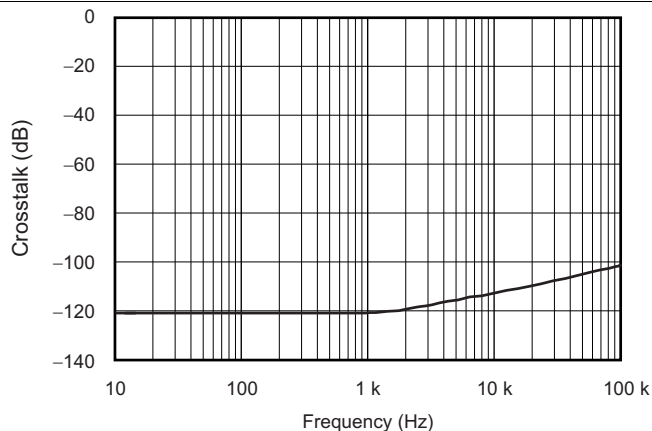


Figure 27. Crosstalk vs Frequency

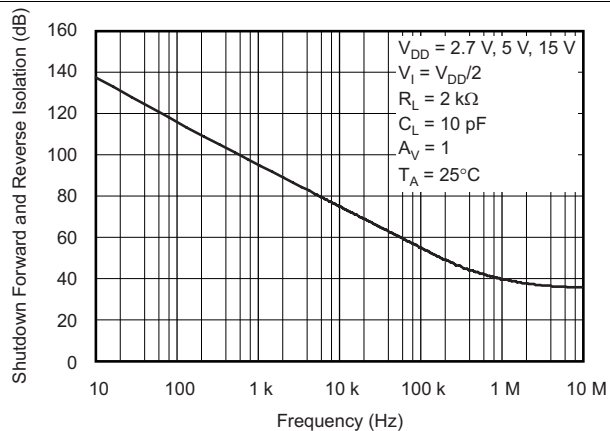


Figure 28. Shutdown Forward and Reverse Isolation vs Frequency

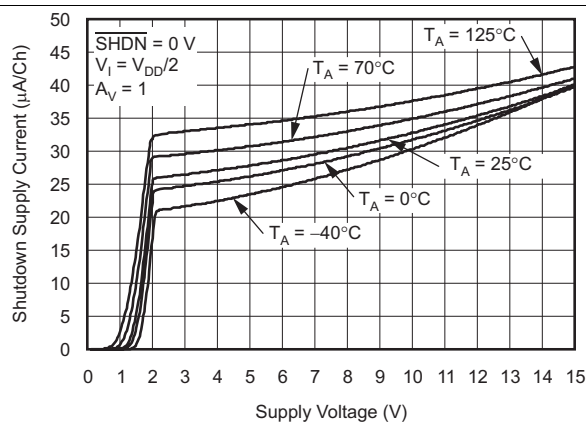


Figure 29. Shutdown Supply Current vs Supply Voltage

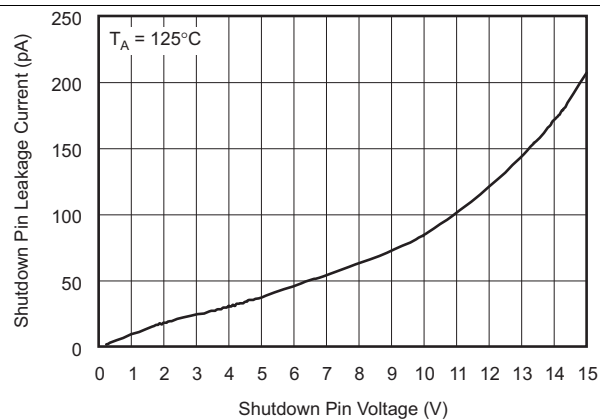


Figure 30. Shutdown Pin Leakage Current vs Shutdown Pin Voltage

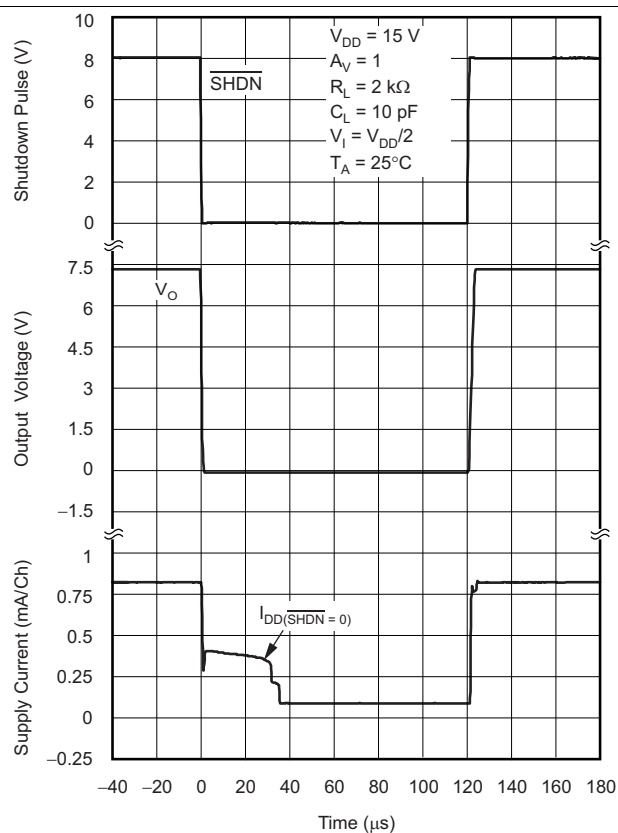


Figure 31. Shutdown Supply Current and Output Voltage vs Time

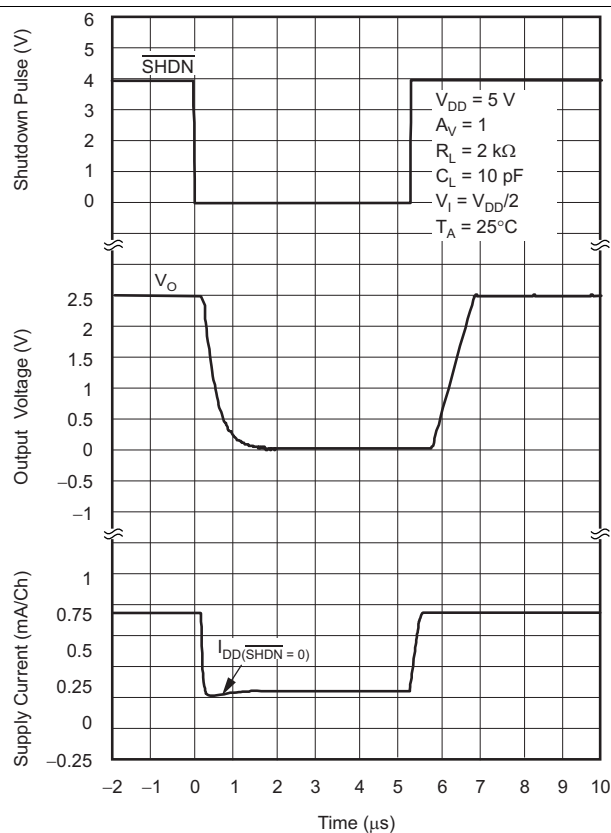


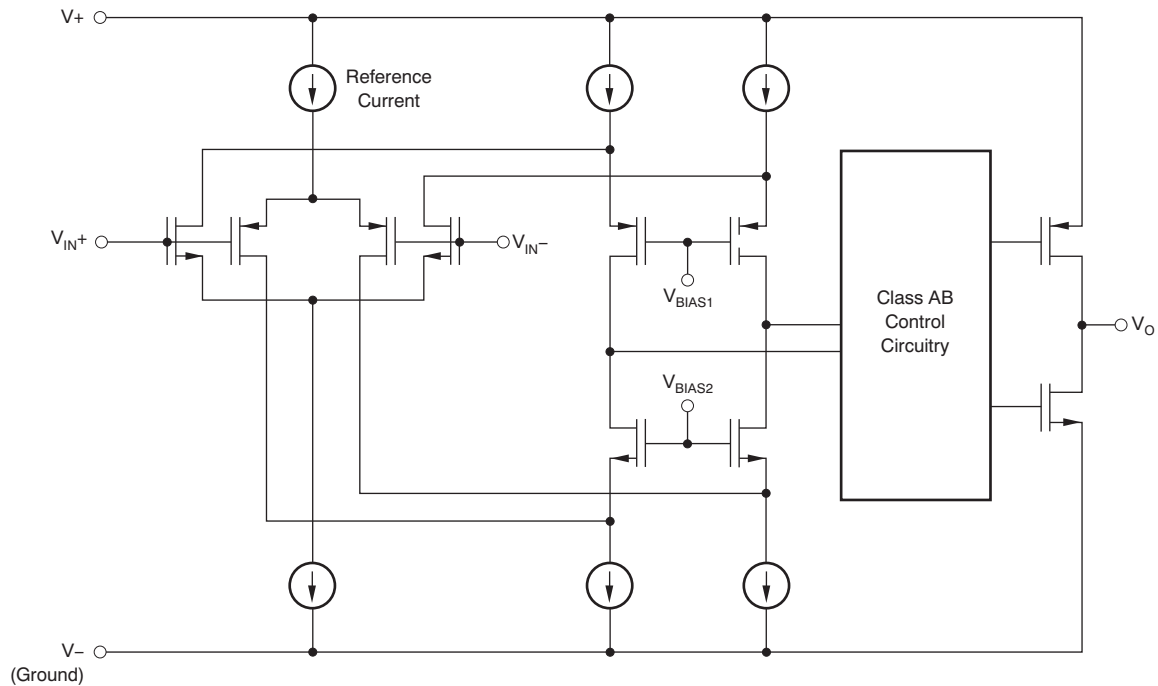
Figure 32. Shutdown Supply Current/output Voltage vs Time

9 Detailed Description

9.1 Overview

The TLV237x single-supply CMOS operational amplifiers provide rail-to-rail input and output capability with 3-MHz bandwidth. Consuming 550 μA , the TLV237x is designed for portable and battery-operated applications. The maximum recommended supply voltage is 16 V, which allows the devices to operate from ($\pm 8\text{-V}$ supplies down to $\pm 1.35\text{ V}$) a variety of rechargeable cells. The rail-to-rail inputs with high input impedance make the TLV237x an option for sensor signal-conditioning applications.

9.2 Functional Block Diagram



9.3 Feature Description

9.3.1 Rail-to-Rail Input Operation

The TLV237x input stage consists of two differential transistor pairs (NMOS and PMOS) that operate together to achieve rail-to-rail input operation. The transition point between these two pairs are shown in [Figure 1](#), [Figure 2](#), and [Figure 3](#) for a 2.7-V, 5-V, and 15-V supply. As the common-mode input voltage approaches the positive supply rail, the input pair switches from the PMOS differential pair to the NMOS differential pair. This transition occurs approximately 1.35 V from the positive rail and results in a change in offset voltage due to different device characteristics between the NMOS and PMOS pairs. If the input signal to the device is large enough to swing between both rails, this transition results in a reduction in common-mode rejection ratio (CMRR). If the input signal does not swing between both rails, bias the signal in the region where only one input pair is active. This is the region in [Figure 1](#) and [Figure 3](#) where the offset voltage varies slightly across the input range and optimal CMRR can be achieved. This has the greatest impact when operating from a 2.7-V supply voltage.

9.3.2 Driving a Capacitive Load

When the amplifier is configured in this manner, capacitive loading directly on the output decreases the device phase margin leading to high frequency ringing or oscillations. Therefore, for capacitive loads of greater than 10 pF, TI recommends placing a resistor in series (R_{NULL}) with the output of the amplifier, as shown in [Figure 33](#). A minimum value of 20 Ω works well for most applications.

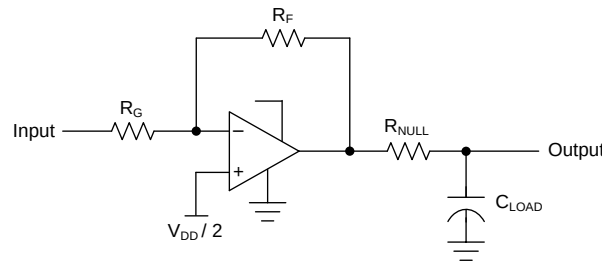
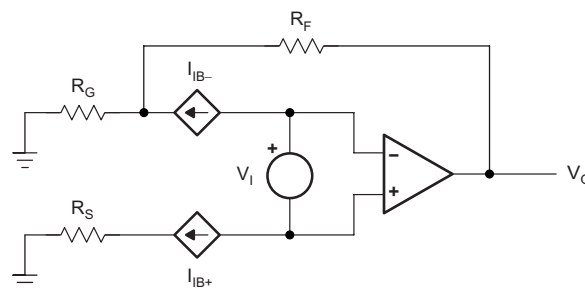


Figure 33. Driving a Capacitive Load

9.3.3 Offset Voltage

The output offset voltage (V_{OO}) is the sum of the input offset voltage (V_{IO}) and input bias currents (I_{IB}) times the corresponding gains. [Figure 34](#) can be used to calculate the output offset voltage. Note that this does not include other parameters that can affect the offset voltage, such as PSRR and CMRR.



$$V_{OO} = V_{IO} \left[1 + \left(\frac{R_F}{R_G} \right) \right] \pm I_{IB+} R_S \left[1 + \left(\frac{R_F}{R_G} \right) \right] \pm I_{IB-} R_F$$

Figure 34. Output Offset Voltage Model

Feature Description (continued)

9.3.4 General Configurations

When receiving low-level signals, limiting the bandwidth of the incoming signals into the system is often required. The simplest way to accomplish this is to place an RC filter at the noninverting terminal. To accomplish this, place an RC filter at the noninverting terminal (see Figure 35).

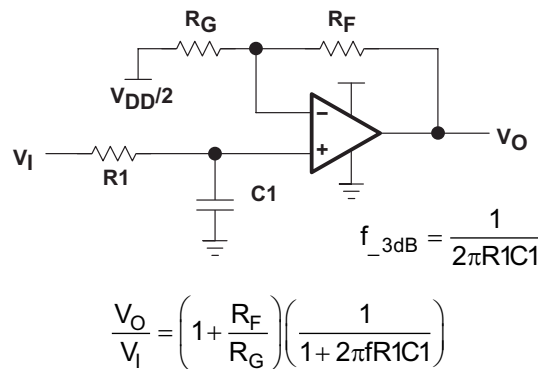


Figure 35. Single-Pole Low-Pass Filter

If even more attenuation is required, a multiple pole filter is required. The Sallen-key filter is used for this task. For best results, the amplifier must have a bandwidth that is eight to 10 times the filter frequency bandwidth. Failure to do this can result in phase shift of the amplifier.

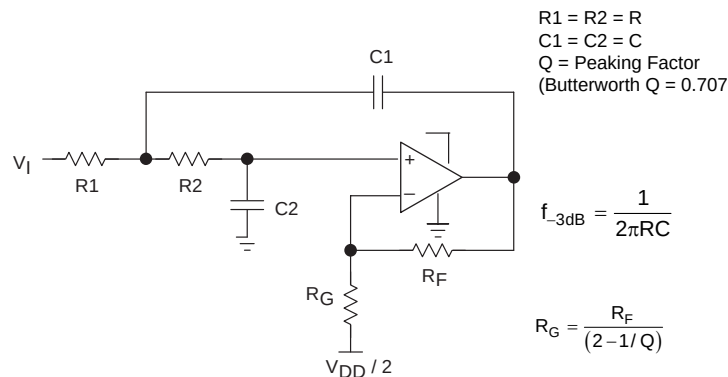


Figure 36. 2-Pole, Low-Pass, Sallen-Key Filter

9.3.5 Shutdown Function

Three members of the TLV237x family (TLV2370, TLV2373, and TLV2375) have a shutdown terminal for conserving battery life in portable applications. When the shutdown terminal is tied low, the supply current is reduced to 25 $\mu\text{A}/\text{channel}$, the amplifier is disabled, and the outputs are placed in a high impedance mode. To enable the amplifier, the shutdown terminal can either be left floating or pulled high. When the shutdown terminal is left floating, take care to ensure that parasitic leakage current at the shutdown terminal does not inadvertently place the operational amplifier into shutdown.

9.4 Device Functional Modes

The TLV2371, TLV2372, and TLV2374 have a single functional mode. These devices are operable as long as the power-supply voltage is between 2.7 V (± 1.35 V) and 16 V (± 8 V).

The TLV2370, TLV2373, and TLV2375 are likewise operational as long as the power-supply voltage is between 2.7 V (± 1.35 V) and 16 V (± 8 V), additionally these devices also have a shutdown capability. When the shutdown control pin is driven below 0.8 V above ground, the device is in shutdown. If the shutdown control pin voltage is driven to greater than 2 V above ground, the device is in its normal operating mode. See [Shutdown Function](#) for additional information regarding shutdown operation.

10 Application and Implementation

NOTE

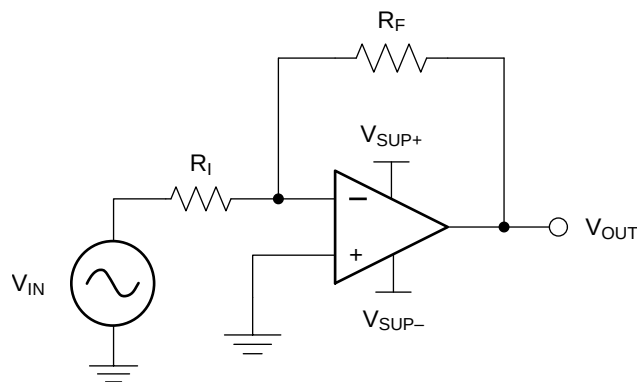
Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

10.1 Application Information

When designing for low power, choose system components carefully. To minimize current consumption, select large-value resistors. Any resistors react with stray capacitance in the circuit and the input capacitance of the operational amplifier. These parasitic RC combinations affect the stability of the overall system. Use of a feedback capacitor assures stability and limits overshoot or gain peaking.

10.2 Typical Application

A typical application for an operational amplifier is an inverting amplifier, as Figure 37 shows. An inverting amplifier takes a positive voltage on the input and outputs a signal inverted to the input, ~~making~~ which results in a negative voltage of the same magnitude. In the same manner, the amplifier makes negative input voltages positive on the output. ~~In addition, amplification can be added by selecting~~ Select the input resistor (R_I) and the feedback resistor (R_F) to add amplification.



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Figure 37. Application Schematic

Typical Application (continued)

10.2.1 Design Requirements

The selected supply voltage must be larger than the input voltage range and the desired output range. Consider the limits of the input common-mode range (V_{CM}) and the output voltage swing to the rails (V_O). For example, this application scales a signal of ± 0.5 V (1 V) to ± 1.8 V (3.6 V). Setting the supply at ± 2.5 V is sufficient to accommodate this application.

10.2.2 Detailed Design Procedure

Determine the gain required by the inverting amplifier using [Equation 1](#) and [Equation 2](#):

$$A_V = \frac{V_{OUT}}{V_{IN}} \quad (1)$$

$$A_V = \frac{1.8}{-0.5} = -3.6 \quad (2)$$

When the desired gain is determined, choose a value for R_I or R_F . Choosing a value in the k Ω range is desirable for general-purpose applications because the amplifier circuit uses currents in the milliamp range. This milliamp current range ensures the device does not draw too much current. The trade-off is that very large resistors (100s of k Ω) draw the smallest current but generate the highest noise. Very small resistors (100s of Ω) generate low noise but draw high current. This example uses 10 k Ω for R_I , meaning 36 k Ω is used for R_F . These values are determined by [Equation 3](#):

$$A_V = -\frac{R_F}{R_I} \quad (3)$$

10.2.3 Application Curve

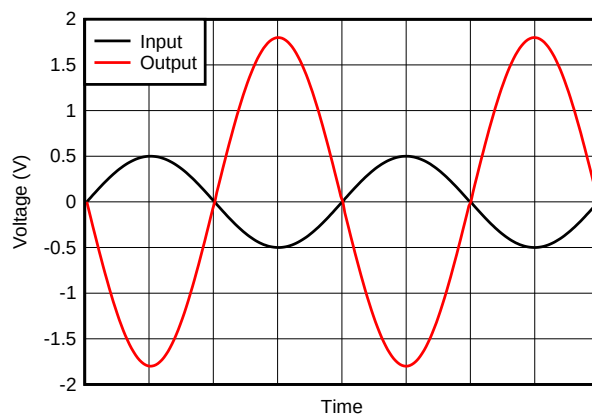


Figure 38. Inverting Amplifier Input and Output

11 Power Supply Recommendations

The TLV237x family is specified for operation from 2.7 V to 16 V (± 1.35 V to ± 8 V); many specifications apply from -40°C to $+125^{\circ}\text{C}$. The [Typical Characteristics](#) presents parameters that can exhibit significant variance with regard to operating voltage or temperature.

CAUTION

Supply voltages larger than 16 V can permanently damage the device (see the [Absolute Maximum Ratings](#) table).

Place 0.1- μF bypass capacitors close to the power-supply pins to reduce errors coupling in from noisy or high-impedance power supplies. For more detailed information on bypass capacitor placement, see [Layout](#).

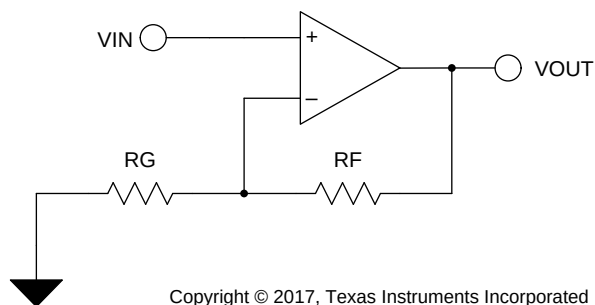
12 Layout

12.1 Layout Guidelines

To achieve the levels of high performance of the TLV237x, follow proper printed-circuit board design techniques. A general set of guidelines is shown in the following list:

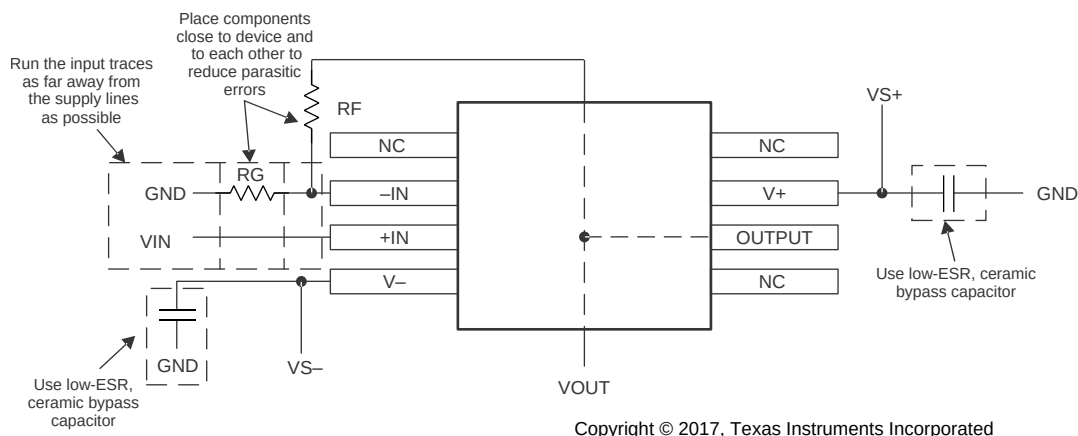
- Ground planes: TI highly recommends using a ground plane on the board to provide all components with a low inductive ground connection. However, in the areas of the amplifier inputs and output, the ground plane can be removed to minimize the stray capacitance.
- Proper power supply decoupling: Use a 6.8- μF tantalum capacitor in parallel with a 0.1- μF ceramic capacitor on each supply ~~terminal~~ pin. It may be possible to share the tantalum among several amplifiers depending on the application ~~but a 0.1- μF ceramic capacitor must always be used on the supply terminal of every amplifier~~. Always use a 0.1- μF ceramic capacitor on the supply pin of every amplifier. In addition, the 0.1- μF capacitor must be placed as close to the supply pin as possible. ~~as possible to the supply terminal~~. As this distance increases, the inductance in the connecting trace makes the capacitor less effective. The designer must strive for distances of less than 0.1 inches between the device power ~~terminals~~ pins and the ceramic capacitors.
- Sockets: Sockets can be used but are not recommended. The additional lead inductance in the socket pins often lead to stability problems. ~~Surface-mount packages soldered directly to the printed-circuit board is the best implementation~~. For best results, solder the surface mount packages directly to the printed circuit board.
- Short trace runs and compact part placements: Optimum high performance is achieved when stray series inductance are minimized. To realize this, the circuit layout must be made as compact as possible, which minimizes the length of all trace runs. Pay particular attention to the inverting input of the amplifier. The length of the inverting input must be kept as short as possible. This helps to minimize stray capacitance at the input of the amplifier.
- Surface-mount passive components: Using surface-mount passive components is recommended for high performance amplifier circuits for several reasons. First, because of the low lead inductance of surface-mount components, the problem with stray series inductance is reduced. Second, the small size of surface-mount components naturally leads to a more compact layout, which minimizes stray inductance and capacitance. TI recommends that lead lengths are kept as short as possible if leaded components are used.

12.2 Layout Example



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Figure 39. Schematic Representation



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Figure 40. Operational Amplifier Board Layout for Noninverting Configuration

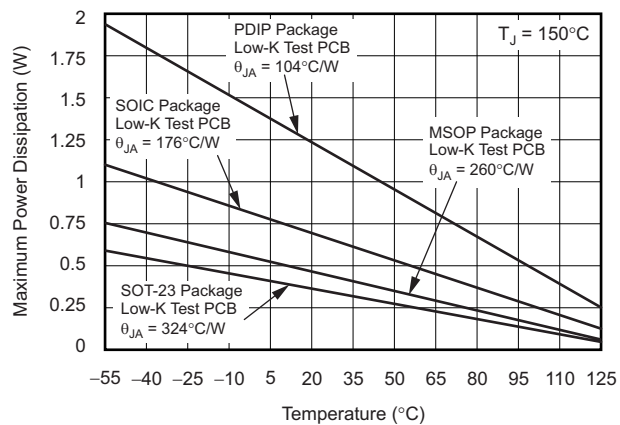
12.3 Power Dissipation Considerations

For a given θ_{JA} value, the maximum power dissipation is shown in Figure 41 and is calculated by Equation 4:

$$P_D = \left[\frac{T_{MAX} - T_A}{\theta_{JA}} \right]$$

where

- P_D = Maximum power dissipation of TLV237x IC (watts)
- T_{MAX} = Absolute maximum junction temperature (150°C)
- T_A = Free-ambient air temperature (°C)
- $\theta_{JA} = \theta_{JC}$ (Thermal coefficient from junction to case) + θ_{CA} (Thermal coefficient from case to ambient air (°C/W)) (4)



Results are with no air flow and using JEDEC Standard Low-K test PCB.

Figure 41. Maximum Power Dissipation vs Free-Air Temperature

13 デバイスおよびドキュメントのサポート

13.1 ドキュメントのサポート

13.1.1 関連資料

関連資料については、以下を参照してください。

[『EVM選択ガイド』\(SLOU060\)](#)

13.2 関連リンク

次の表に、クイック・アクセス・リンクを示します。カテゴリには、技術資料、サポートおよびコミュニティ・リソース、ツールとソフトウェア、およびご注文へのクイック・アクセスが含まれます。

表 4. 関連リンク

製品	プロダクト・フォルダ	ご注文はこちら	技術資料	ツールとソフトウェア	サポートとコミュニティ
TLV2370	ここをクリック	ここをクリック	ここをクリック	ここをクリック	ここをクリック
TLV2371	ここをクリック	ここをクリック	ここをクリック	ここをクリック	ここをクリック
TLV2372	ここをクリック	ここをクリック	ここをクリック	ここをクリック	ここをクリック
TLV2373	ここをクリック	ここをクリック	ここをクリック	ここをクリック	ここをクリック
TLV2374	ここをクリック	ここをクリック	ここをクリック	ここをクリック	ここをクリック
TLV2375	ここをクリック	ここをクリック	ここをクリック	ここをクリック	ここをクリック

13.3 ドキュメントの更新通知を受け取る方法

ドキュメントの更新についての通知を受け取るには、ti.comのデバイス製品フォルダを開いてください。右上の隅にある「通知を受け取る」をクリックして登録すると、変更されたすべての製品情報に関するダイジェストを毎週受け取れます。変更の詳細については、修正されたドキュメントに含まれている改訂履歴をご覧ください。

13.4 コミュニティ・リソース

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

TI E2E™ オンライン・コミュニティ *TIのE2E (Engineer-to-Engineer)* コミュニティ。エンジニア間の共同作業を促進するために開設されたものです。e2e.ti.comでは、他のエンジニアに質問し、知識を共有し、アイデアを検討して、問題解決に役立てることができます。

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13.5 商標

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13.6 静電気放電に関する注意事項



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静電気放電はわずかな性能の低下から完全なデバイスの故障に至るまで、様々な損傷を与えます。高精度の集積回路は、損傷に対して敏感であり、極めてわずかなパラメータの変化により、デバイスに規定された仕様に適合しなくなる場合があります。

13.7 Glossary

SLYZ022 — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

14 メカニカル、パッケージ、および注文情報

以降のページには、メカニカル、パッケージ、および注文に関する情報が記載されています。この情報は、そのデバイスについて利用可能な最新のデータです。このデータは予告なく変更されることがあり、ドキュメントが改訂される場合もあります。本データシートのブラウザ版を使用されている場合は、画面左側の説明をご覧ください。

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TLV2370ID	Obsolete	Production	SOIC (D) 8	-	-	Call TI	Call TI	-40 to 125	2370I
TLV2370IDBVR	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	VBFI
TLV2370IDBVR.A	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	VBFI
TLV2370IDBVR.B	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	VBFI
TLV2370IDBVR1G4	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	VBFI
TLV2370IDBVR1G4.A	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	VBFI
TLV2370IDBVR1G4.B	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	VBFI
TLV2370IDBVT	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	VBFI
TLV2370IDBVT.A	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	VBFI
TLV2370IDBVT.B	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	VBFI
TLV2370IDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2370I
TLV2370IDR.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2370I
TLV2370IP	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	2370I
TLV2370IP.B	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	2370I
TLV2371ID	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2371I
TLV2371ID.B	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2371I
TLV2371IDBVR	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	VBGI
TLV2371IDBVR.B	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	VBGI
TLV2371IDBVT	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	VBGI
TLV2371IDBVT.B	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	VBGI
TLV2371IDG4	Active	Production	SOIC (D) 8	75 TUBE	-	Call TI	Call TI	-40 to 125	
TLV2371IDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2371I
TLV2371IDR.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2371I
TLV2371IDRG4	Active	Production	SOIC (D) 8	2500 LARGE T&R	-	Call TI	Call TI	-40 to 125	
TLV2371IP	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	2371I
TLV2371IP.B	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	2371I
TLV2371IPE4	Active	Production	PDIP (P) 8	50 TUBE	-	Call TI	Call TI	-40 to 125	
TLV2372ID	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2372I
TLV2372ID.A	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2372I

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TLV2372ID.B	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2372I
TLV2372IDGK	Active	Production	VSSOP (DGK) 8	80 TUBE	Yes	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	APG
TLV2372IDGK.A	Active	Production	VSSOP (DGK) 8	80 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	APG
TLV2372IDGK.B	Active	Production	VSSOP (DGK) 8	80 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	APG
TLV2372IDGKG4	Active	Production	VSSOP (DGK) 8	80 TUBE	-	Call TI	Call TI	-40 to 125	
TLV2372IDGKR	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	APG
TLV2372IDGKR.A	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	APG
TLV2372IDGKR.B	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	APG
TLV2372IDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2372I
TLV2372IDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2372I
TLV2372IDR.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2372I
TLV2372IDRG4	Active	Production	SOIC (D) 8	2500 LARGE T&R	-	Call TI	Call TI	-40 to 125	
TLV2372IP	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	2372I
TLV2372IP.A	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	2372I
TLV2372IP.B	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	2372I
TLV2372IPE4	Active	Production	PDIP (P) 8	50 TUBE	-	Call TI	Call TI	-40 to 125	
TLV2373ID	Obsolete	Production	SOIC (D) 14	-	-	Call TI	Call TI	-40 to 125	2373I
TLV2373IDGS	Active	Production	VSSOP (DGS) 10	80 TUBE	Yes	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	API
TLV2373IDGS.A	Active	Production	VSSOP (DGS) 10	80 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	API
TLV2373IDGS.B	Active	Production	VSSOP (DGS) 10	80 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	API
TLV2373IDGSR	Active	Production	VSSOP (DGS) 10	2500 LARGE T&R	Yes	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	API
TLV2373IDGSR.A	Active	Production	VSSOP (DGS) 10	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	API
TLV2373IDGSR.B	Active	Production	VSSOP (DGS) 10	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	API
TLV2373IDGSRG4	Active	Production	VSSOP (DGS) 10	2500 LARGE T&R	-	Call TI	Call TI	-40 to 125	
TLV2373IDR	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2373I
TLV2373IDR.A	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2373I
TLV2373IDR.B	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2373I
TLV2373IN	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLV2373I
TLV2373IN.A	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLV2373I
TLV2374ID	Active	Production	SOIC (D) 14	50 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2374I
TLV2374ID.A	Active	Production	SOIC (D) 14	50 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2374I

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TLV2374ID.B	Active	Production	SOIC (D) 14	50 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2374I
TLV2374IDG4	Active	Production	SOIC (D) 14	50 TUBE	-	Call TI	Call TI	-40 to 125	
TLV2374IDR	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2374I
TLV2374IDR.A	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2374I
TLV2374IDR.B	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2374I
TLV2374IN	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	2374I
TLV2374IN.A	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	2374I
TLV2374IN.B	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	2374I
TLV2374IPW	Active	Production	TSSOP (PW) 14	90 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2374I
TLV2374IPW.A	Active	Production	TSSOP (PW) 14	90 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2374I
TLV2374IPW.B	Active	Production	TSSOP (PW) 14	90 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2374I
TLV2374IPWR	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	2374I
TLV2374IPWR.A	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2374I
TLV2374IPWR.B	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2374I
TLV2374IPWRG4	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	-	Call TI	Call TI	-40 to 125	
TLV2375ID	Active	Production	SOIC (D) 16	40 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2375I
TLV2375ID.A	Active	Production	SOIC (D) 16	40 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2375I
TLV2375ID.B	Active	Production	SOIC (D) 16	40 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2375I
TLV2375IDR	Active	Production	SOIC (D) 16	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2375I
TLV2375IDR.A	Active	Production	SOIC (D) 16	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2375I
TLV2375IDR.B	Active	Production	SOIC (D) 16	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2375I
TLV2375IN	Active	Production	PDIP (N) 16	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	2375I
TLV2375IN.A	Active	Production	PDIP (N) 16	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	2375I
TLV2375IN.B	Active	Production	PDIP (N) 16	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	2375I
TLV2375IPW	Active	Production	TSSOP (PW) 16	90 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2375I
TLV2375IPW.A	Active	Production	TSSOP (PW) 16	90 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2375I
TLV2375IPW.B	Active	Production	TSSOP (PW) 16	90 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2375I
TLV2375IPWR	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2375I
TLV2375IPWR.A	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2375I
TLV2375IPWR.B	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2375I
TLV2375IPWRG4	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	-	Call TI	Call TI	-40 to 125	

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

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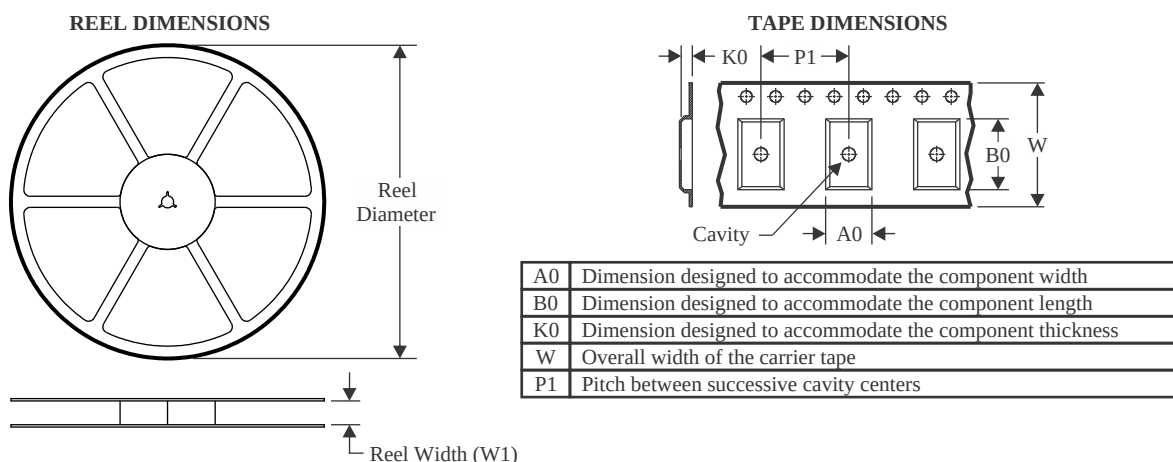
OTHER QUALIFIED VERSIONS OF TLV2371, TLV2372, TLV2374 :

- Automotive : [TLV2371-Q1](#), [TLV2372-Q1](#), [TLV2374-Q1](#)
- Enhanced Product : [TLV2374-EP](#)

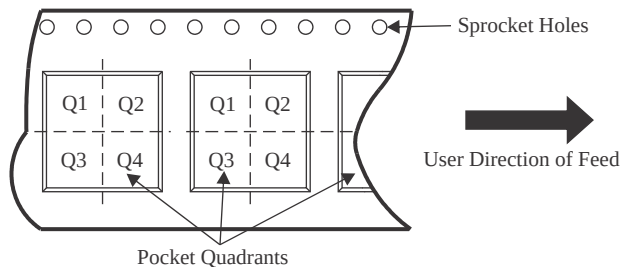
NOTE: Qualified Version Definitions:

- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product - Supports Defense, Aerospace and Medical Applications

TAPE AND REEL INFORMATION



QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLV2370IDBVR	SOT-23	DBV	6	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TLV2370IDBVR1G4	SOT-23	DBV	6	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TLV2370IDBVT	SOT-23	DBV	6	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TLV2370IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2371IDBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TLV2371IDBVT	SOT-23	DBV	5	250	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3
TLV2371IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2372IDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLV2372IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2373IDGSR	VSSOP	DGS	10	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLV2373IDGSR	VSSOP	DGS	10	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLV2373IDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TLV2374IDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TLV2374IPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TLV2374IPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TLV2375IDR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1

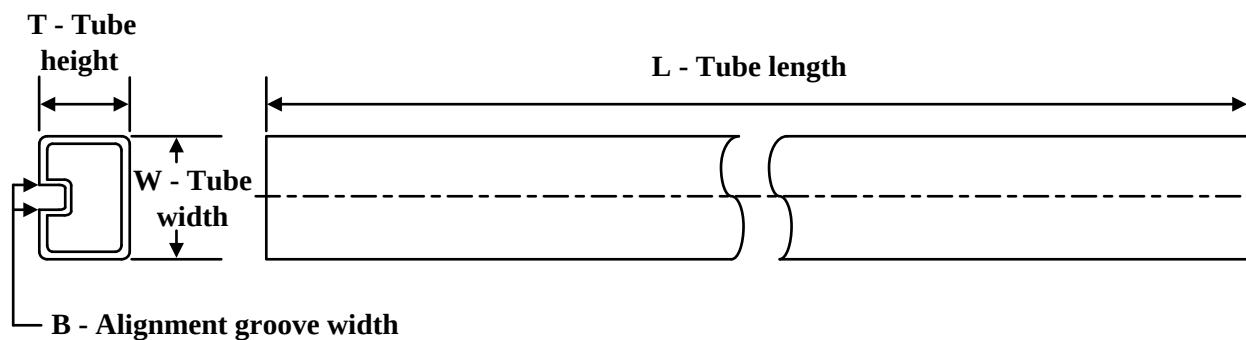
Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLV2375IPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLV2370IDBVR	SOT-23	DBV	6	3000	210.0	185.0	35.0
TLV2370IDBVR1G4	SOT-23	DBV	6	3000	210.0	185.0	35.0
TLV2370IDBVT	SOT-23	DBV	6	250	210.0	185.0	35.0
TLV2370IDR	SOIC	D	8	2500	353.0	353.0	32.0
TLV2371IDBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
TLV2371IDBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
TLV2371IDR	SOIC	D	8	2500	353.0	353.0	32.0
TLV2372IDGKR	VSSOP	DGK	8	2500	364.0	364.0	27.0
TLV2372IDR	SOIC	D	8	2500	353.0	353.0	32.0
TLV2373IDGSR	VSSOP	DGS	10	2500	364.0	364.0	27.0
TLV2373IDGSR	VSSOP	DGS	10	2500	358.0	335.0	35.0
TLV2373IDR	SOIC	D	14	2500	353.0	353.0	32.0
TLV2374IDR	SOIC	D	14	2500	353.0	353.0	32.0
TLV2374IPWR	TSSOP	PW	14	2000	356.0	356.0	35.0
TLV2374IPWR	TSSOP	PW	14	2000	353.0	353.0	32.0
TLV2375IDR	SOIC	D	16	2500	353.0	353.0	32.0
TLV2375IPWR	TSSOP	PW	16	2000	353.0	353.0	32.0

TUBE


*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
TLV2370IP	P	PDIP	8	50	506	13.97	11230	4.32
TLV2370IP.B	P	PDIP	8	50	506	13.97	11230	4.32
TLV2371ID	D	SOIC	8	75	507	8	3940	4.32
TLV2371ID.B	D	SOIC	8	75	507	8	3940	4.32
TLV2371IP	P	PDIP	8	50	506	13.97	11230	4.32
TLV2371IP.B	P	PDIP	8	50	506	13.97	11230	4.32
TLV2372ID	D	SOIC	8	75	507	8	3940	4.32
TLV2372ID.A	D	SOIC	8	75	507	8	3940	4.32
TLV2372ID.B	D	SOIC	8	75	507	8	3940	4.32
TLV2372IDGK	DGK	VSSOP	8	80	330	6.55	500	2.88
TLV2372IDGK.A	DGK	VSSOP	8	80	330	6.55	500	2.88
TLV2372IDGK.B	DGK	VSSOP	8	80	330	6.55	500	2.88
TLV2372IP	P	PDIP	8	50	506	13.97	11230	4.32
TLV2372IP.A	P	PDIP	8	50	506	13.97	11230	4.32
TLV2372IP.B	P	PDIP	8	50	506	13.97	11230	4.32
TLV2373IDGS	DGS	VSSOP	10	80	330	6.55	500	2.88
TLV2373IDGS.A	DGS	VSSOP	10	80	330	6.55	500	2.88
TLV2373IDGS.B	DGS	VSSOP	10	80	330	6.55	500	2.88
TLV2373IN	N	PDIP	14	25	506	13.97	11230	4.32
TLV2373IN.A	N	PDIP	14	25	506	13.97	11230	4.32
TLV2374ID	D	SOIC	14	50	507	8	3940	4.32
TLV2374ID.A	D	SOIC	14	50	507	8	3940	4.32
TLV2374ID.B	D	SOIC	14	50	507	8	3940	4.32
TLV2374IN	N	PDIP	14	25	506	13.97	11230	4.32
TLV2374IN.A	N	PDIP	14	25	506	13.97	11230	4.32
TLV2374IN.B	N	PDIP	14	25	506	13.97	11230	4.32
TLV2374IPW	PW	TSSOP	14	90	530	10.2	3600	3.5
TLV2374IPW.A	PW	TSSOP	14	90	530	10.2	3600	3.5
TLV2374IPW.B	PW	TSSOP	14	90	530	10.2	3600	3.5

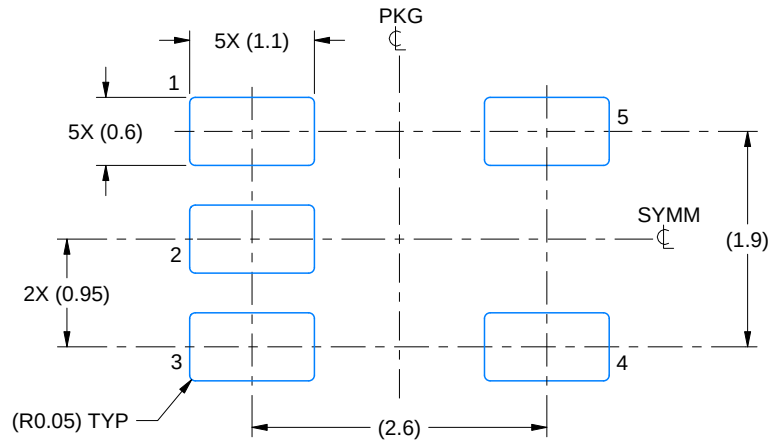
Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
TLV2375ID	D	SOIC	16	40	507	8	3940	4.32
TLV2375ID.A	D	SOIC	16	40	507	8	3940	4.32
TLV2375ID.B	D	SOIC	16	40	507	8	3940	4.32
TLV2375IN	N	PDIP	16	25	506	13.97	11230	4.32
TLV2375IN.A	N	PDIP	16	25	506	13.97	11230	4.32
TLV2375IN.B	N	PDIP	16	25	506	13.97	11230	4.32
TLV2375IPW	PW	TSSOP	16	90	530	10.2	3600	3.5
TLV2375IPW.A	PW	TSSOP	16	90	530	10.2	3600	3.5
TLV2375IPW.B	PW	TSSOP	16	90	530	10.2	3600	3.5

EXAMPLE BOARD LAYOUT

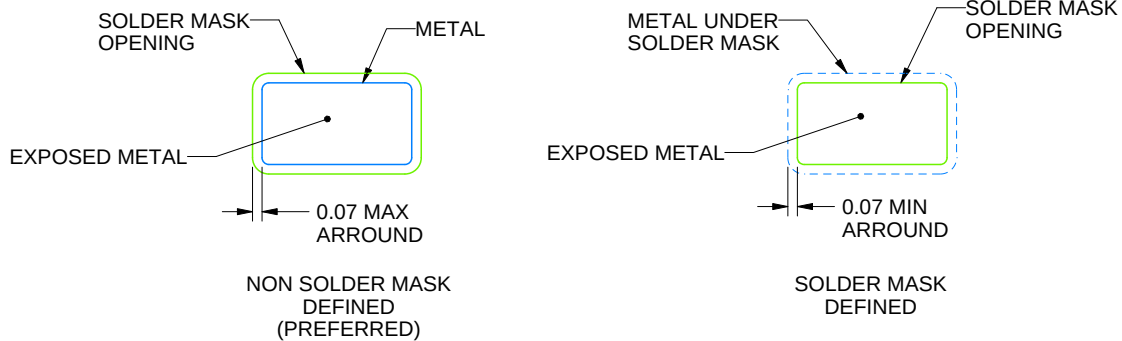
DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X



SOLDER MASK DETAILS

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NOTES: (continued)

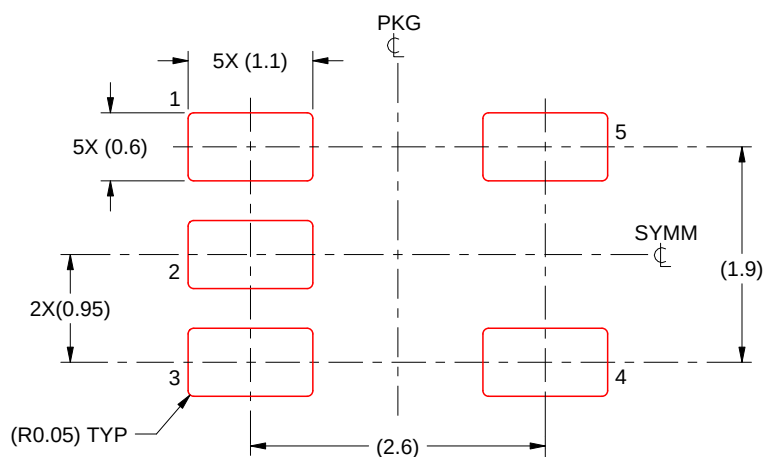
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

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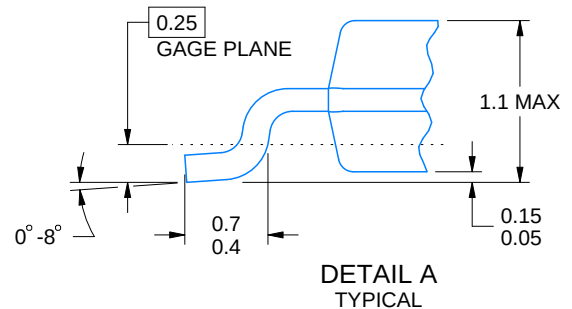
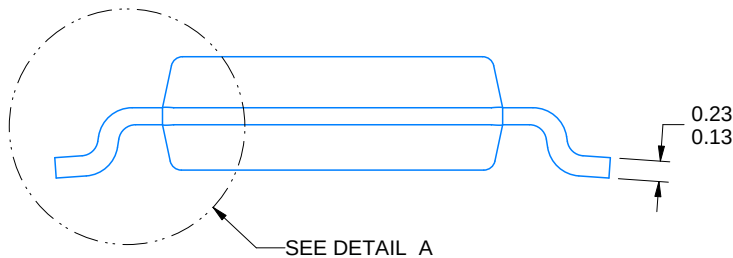
NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.



VSSOP - 1.1 mm max height

Technical drawing of a 6-pin connector. The drawing includes a top view and a side view. The top view shows a rectangular body with six pins on the right side. Dimensions include a total width of 5.05 (typical) and 4.75, a pin pitch of 1.95 (2X), and a pin width of 0.65 (6X). A circular feature is labeled "PIN 1 INDEX AREA". The side view shows the profile of the connector with a seating plane. Callouts include "A", "B", "C", "D", "E", "F", "G", "H", "I", "J", "K", "L", "M", "N", "O", "P", "Q", "R", "S", "T", "U", "V", "W", "X", "Y", "Z", "AA", "AB", "AC", "AD", "AE", "AF", "AG", "AH", "AI", "AJ", "AK", "AL", "AM", "AN", "AO", "AP", "AQ", "AR", "AS", "AT", "AU", "AV", "AW", "AX", "AY", "AZ", "BA", "BB", "BC", "BD", "BE", "BF", "BG", "BH", "BI", "BJ", "BK", "BL", "BM", "BN", "BO", "BP", "BQ", "BR", "BS", "BT", "BU", "BV", "BW", "BX", "BY", "BZ", "CA", "CB", "CC", "CD", "CE", "CF", "CG", "CH", "CI", "CJ", "CK", "CL", "CM", "CN", "CO", "CP", "CQ", "CR", "CS", "CT", "CU", "CV", "CW", "CX", "CY", "CZ", "DA", "DB", "DC", "DD", "DE", "DF", "DG", "DH", "DI", "DJ", "DK", "DL", "DM", "DN", "DO", "DP", "DQ", "DR", "DS", "DT", "DU", "DV", "DW", "DX", "DY", "DZ", "EA", "EB", "EC", "ED", "EE", "EF", "EG", "EH", "EI", "EJ", "EK", "EL", "EM", "EN", "EO", "EP", "EQ", "ER", "ES", "ET", "EU", "EV", "EW", "EX", "EY", "EZ", "FA", "FB", "FC", "FD", "FE", "FF", "FG", "FH", "FI", "FJ", "FK", "FL", "FM", "FN", "FO", "FP", "FQ", "FR", "FS", "FT", "FU", "FV", "FW", "FX", "FY", "FZ", "GA", "GB", "GC", "GD", "GE", "GF", "GG", "GH", "GI", "GJ", "GK", "GL", "GM", "GN", "GO", "GP", "GQ", "GR", "GS", "GT", "GU", "GV", "GW", "GX", "GY", "GZ", "HA", "HB", "HC", "HD", "HE", "HF", "HG", "HH", "HI", "HJ", "HK", "HL", "HM", "HN", "HO", "HP", "HQ", "HR", "HS", "HT", "HU", "HV", "HW", "HX", "HY", "HZ", "IA", "IB", "IC", "ID", "IE", "IF", "IG", "IH", "II", "IJ", "IK", "IL", "IM", "IN", "IO", "IP", "IQ", "IR", "IS", "IT", "IU", "IV", "IW", "IX", "IY", "IZ", "JA", "JB", "JC", "JD", "JE", "JF", "JG", "JH", "JI", "JJ", "JK", "JL", "JM", "JN", "JO", "JP", "JQ", "JR", "JS", "JT", "JU", "JV", "JW", "JX", "JY", "JZ", "KA", "KB", "KC", "KD", "KE", "KF", "KG", "KH", "KI", "KJ", "KK", "KL", "KM", "KN", "KO", "KP", "KQ", "KR", "KS", "KT", "KU", "KV", "KW", "KX", "KY", "KZ", "LA", "LB", "LC", "LD", "LE", "LF", "LG", "LH", "LI", "LJ", "LK", "LL", "LM", "LN", "LO", "LP", "LQ", "LR", "LS", "LT", "LU", "LV", "LW", "LX", "LY", "LZ", "MA", "MB", "MC", "MD", "ME", "MF", "MG", "MH", "MI", "MJ", "MK", "ML", "MM", "MN", "MO", "MP", "MQ", "MR", "MS", "MT", "MU", "MV", "MW", "MX", "MY", "MZ", "NA", "NB", "NC", "ND", "NE", "NF", "NG", "NH", "NI", "NJ", "NK", "NL", "NM", "NN", "NO", "NP", "NQ", "NR", "NS", "NT", "NU", "NV", "NW", "NX", "NY", "NZ", "OA", "OB", "OC", "OD", "OE", "OF", "OG", "OH", "OI", "OJ", "OK", "OL", "OM", "ON", "OO", "OP", "OQ", "OR", "OS", "OT", "OU", "OV", "OW", "OX", "OY", "OZ", "PA", "PB", "PC", "PD", "PE", "PF", "PG", "PH", "PI", "PJ", "PK", "PL", "PM", "PN", "PO", "PP", "PQ", "PR", "PS", "PT", "PU", "PV", "PW", "PX", "PY", "PZ", "QA", "QB", "QC", "QD", "QE", "QF", "QG", "QH", "QI", "QJ", "QK", "QL", "QM", "QN", "QO", "QP", "QQ", "QR", "QS", "QT", "QU", "QV", "QW", "QX", "QY", "QZ", "RA", "RB", "RC", "RD", "RE", "RF", "RG", "RH", "RI", "RJ", "RK", "RL", "RM", "RN", "RO", "RP", "RQ", "RR", "RS", "RT", "RU", "RV", "RW", "RX", "RY", "RZ", "SA", "SB", "SC", "SD", "SE", "SF", "SG", "SH", "SI", "SJ", "SK", "SL", "SM", "SN", "SO", "SP", "SQ", "SR", "SS", "ST", "SU", "SV", "SW", "SX", "SY", "SZ", "TA", "TB", "TC", "TD", "TE", "TF", "TG", "TH", "TI", "TJ", "TK", "TL", "TM", "TN", "TO", "TP", "TQ", "TR", "TS", "TT", "TU", "TV", "TW", "TX", "TY", "TZ", "UA", "UB", "UC", "UD", "UE", "UF", "UG", "UH", "UI", "UJ", "UK", "UL", "UM", "UN", "UO", "UP", "UQ", "UR", "US", "UT", "UU", "UV", "UW", "UX", "UY", "UZ", "VA", "VB", "VC", "VD", "VE", "VF", "VG", "VH", "VI", "VJ", "VK", "VL", "VM", "VN", "VO", "VP", "VQ", "VR", "VS", "VT", "VU", "VV", "VW", "VX", "VY", "VZ", "WA", "WB", "WC", "WD", "WE", "WF", "WG", "WH", "WI", "WJ", "WK", "WL", "WM", "WN", "WO", "WP", "WQ", "WR", "WS", "WT", "WU", "WV", "WW", "WX", "WY", "WZ", "XA", "XB", "XC", "XD", "XE", "XF", "XG", "XH", "XI", "XJ", "XK", "XL", "XM", "XN", "XO", "XP", "XQ", "XR", "XS", "XT", "XU", "XV", "XW", "XX", "XY", "XZ", "YA", "YB", "YC", "YD", "YE", "YF", "YG", "YH", "YI", "YJ", "YK", "YL", "YM", "YN", "YO", "YP", "YQ", "YR", "YS", "YT", "YU", "YV", "YW", "YX", "YY", "YZ", "ZA", "ZB", "ZC", "ZD", "ZE", "ZF", "ZG", "ZH", "ZI", "ZJ", "ZK", "ZL", "ZM", "ZN", "ZO", "ZP", "ZQ", "ZR", "ZS", "ZT", "ZU", "ZV", "ZW", "ZX", "ZY", "ZZ".



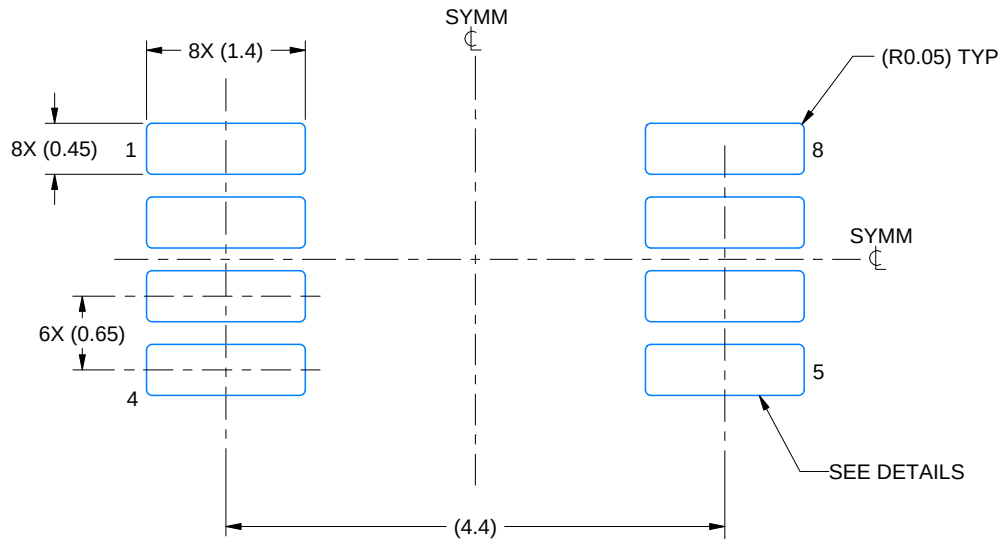
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187.

EXAMPLE BOARD LAYOUT

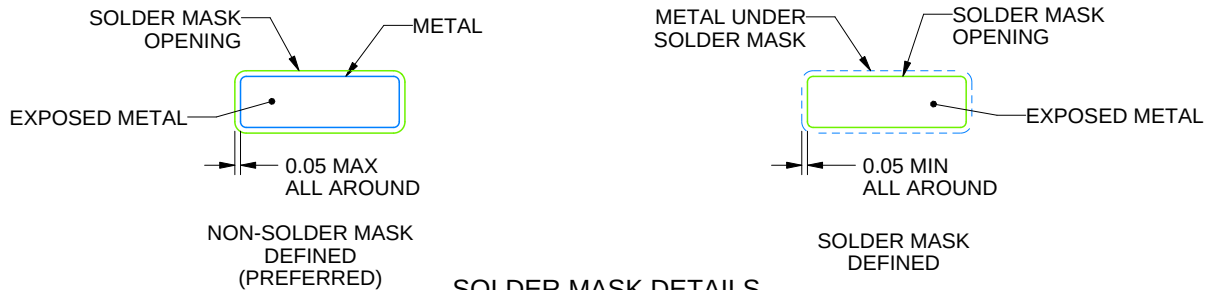
DGK0008A

TM VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 15X



SOLDER MASK DETAILS

4214862/A 04/2023

NOTES: (continued)

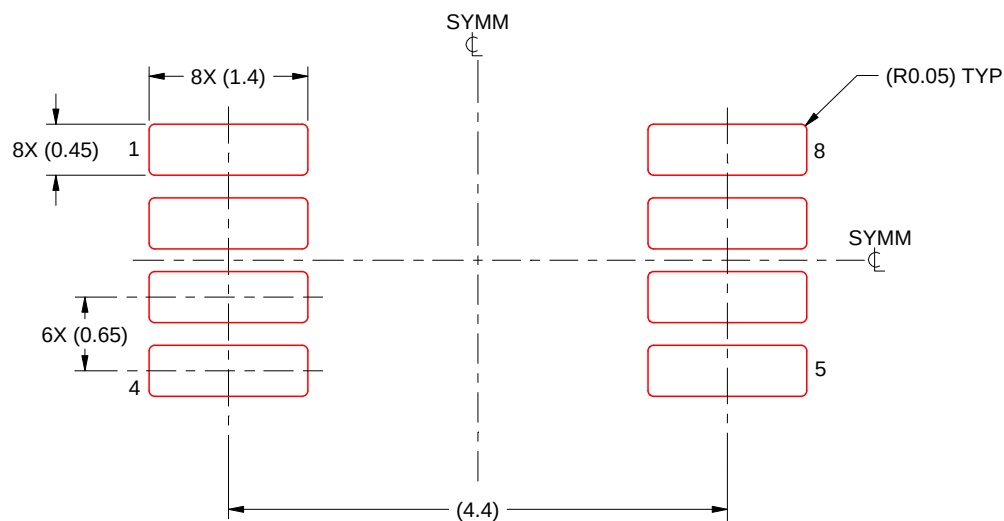
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
9. Size of metal pad may vary due to creepage requirement.

EXAMPLE STENCIL DESIGN

DGK0008A

TM VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE

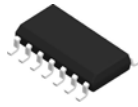


SOLDER PASTE EXAMPLE
SCALE: 15X

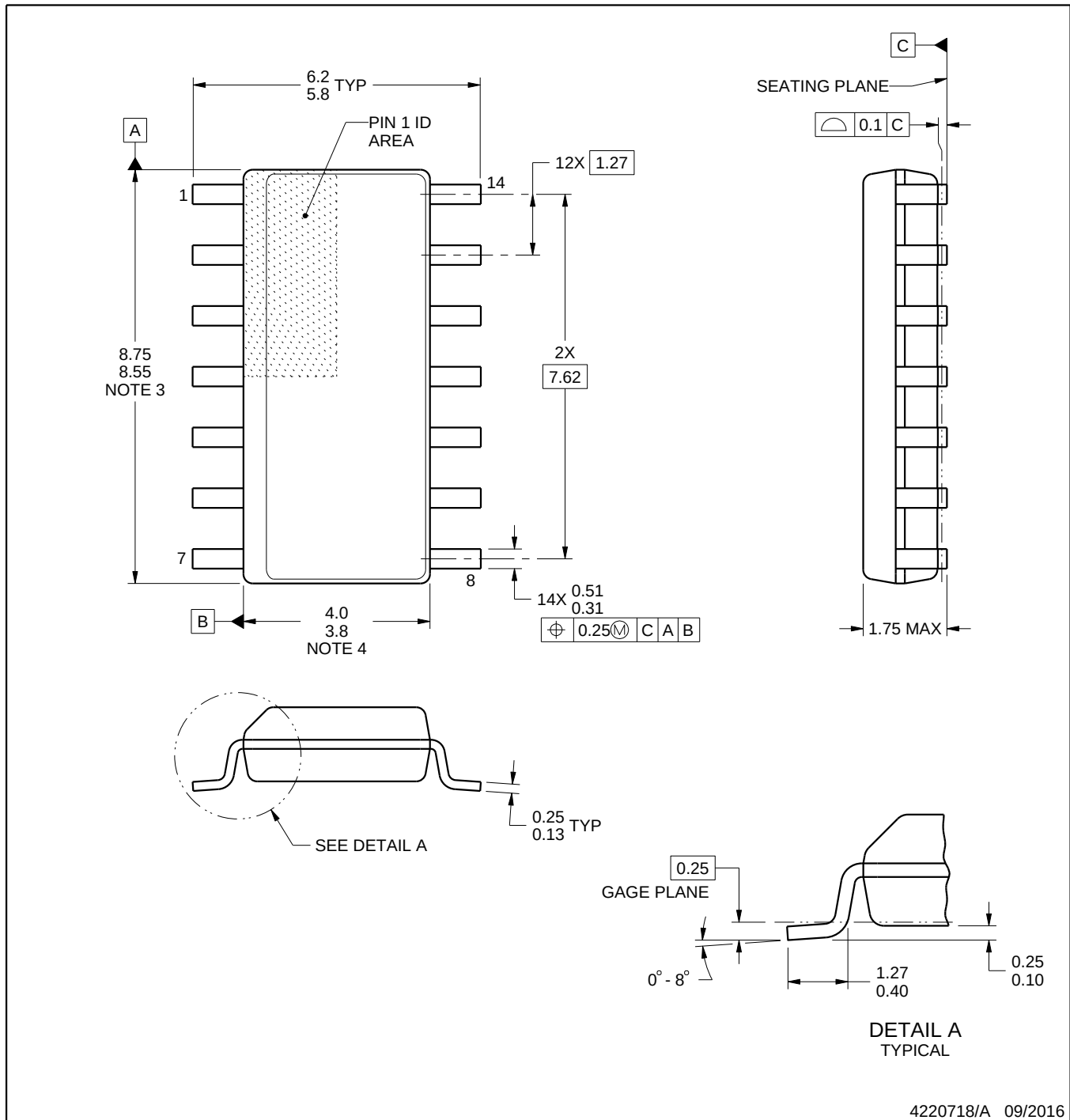
4214862/A 04/2023

NOTES: (continued)

11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
12. Board assembly site may have different recommendations for stencil design.

D0014A**PACKAGE OUTLINE****SOIC - 1.75 mm max height**

SMALL OUTLINE INTEGRATED CIRCUIT



4220718/A 09/2016

NOTES:

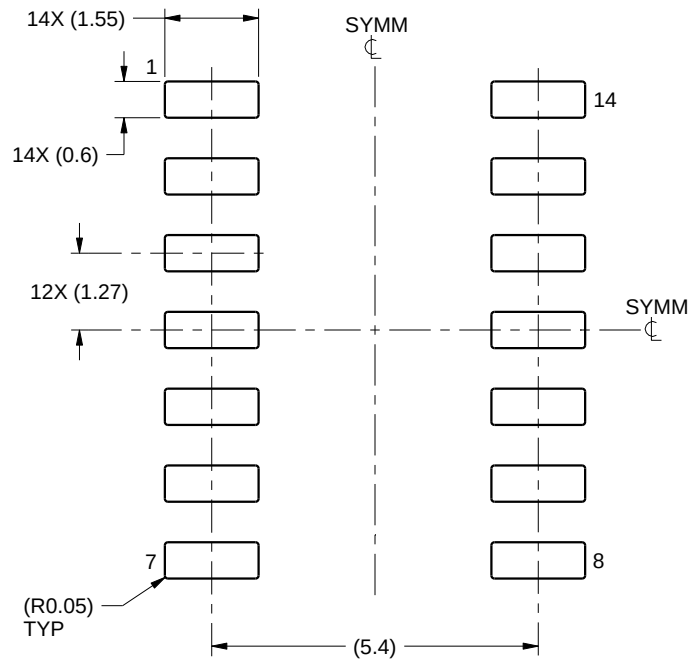
1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm, per side.
5. Reference JEDEC registration MS-012, variation AB.

EXAMPLE BOARD LAYOUT

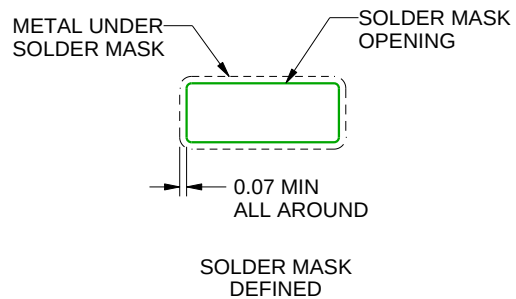
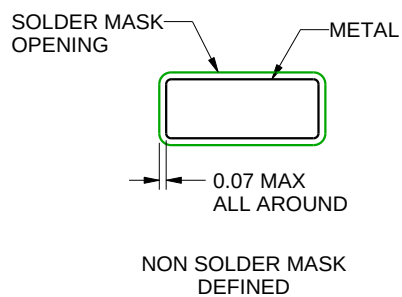
D0014A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE
SCALE:8X



SOLDER MASK DETAILS

4220718/A 09/2016

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

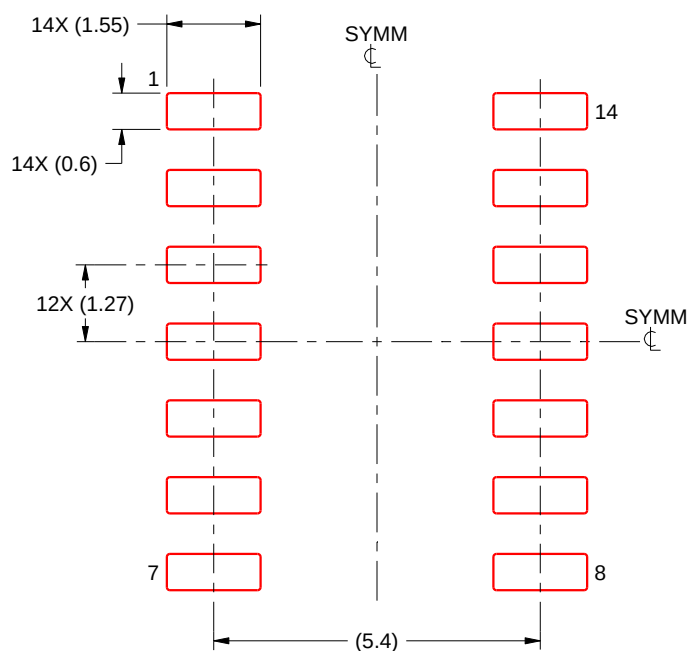
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0014A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:8X

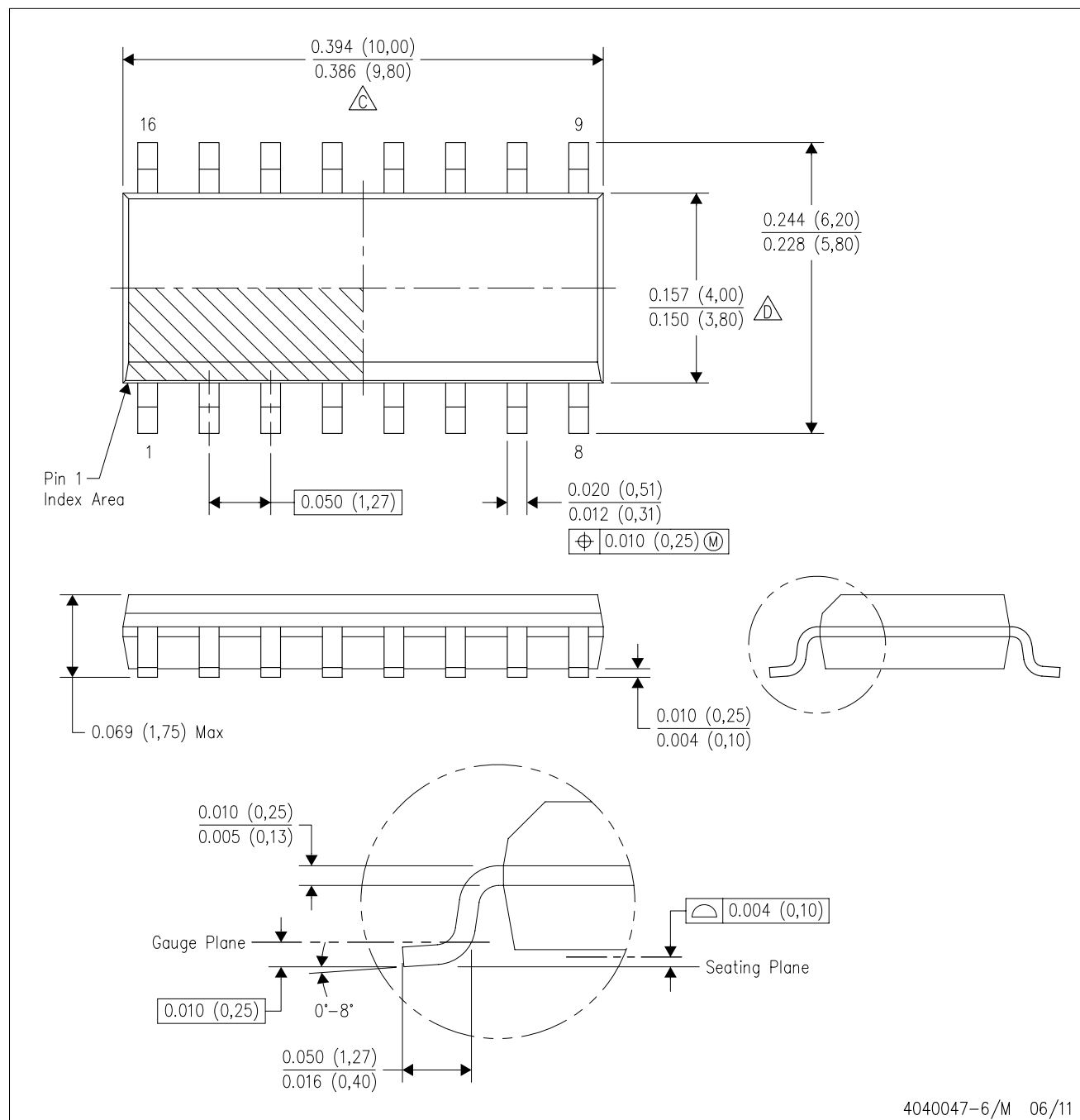
4220718/A 09/2016

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



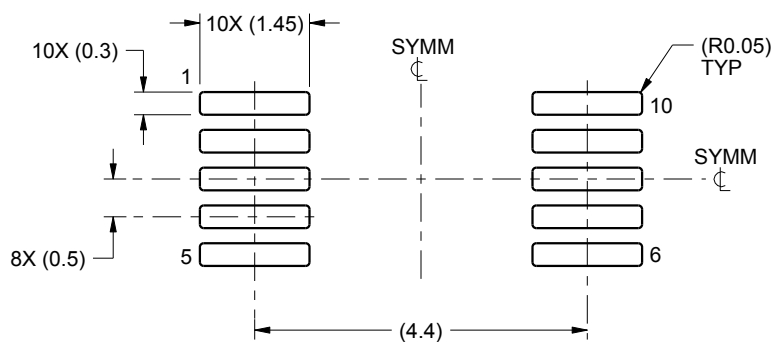
- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 -  C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
 -  D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
 - E. Reference JEDEC MS-012 variation AC.

EXAMPLE BOARD LAYOUT

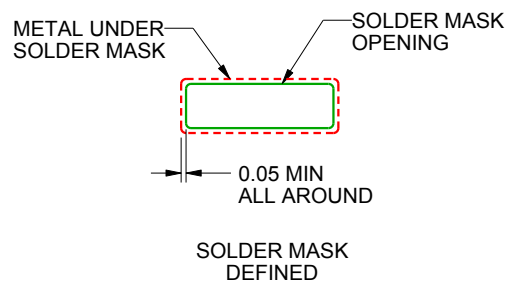
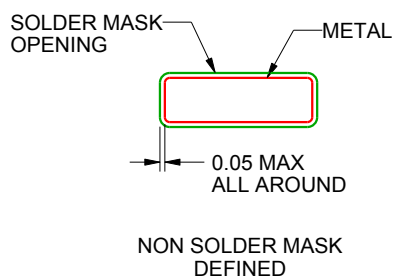
DGS0010A

VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
SCALE:10X



SOLDER MASK DETAILS
NOT TO SCALE

4221984/A 05/2015

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

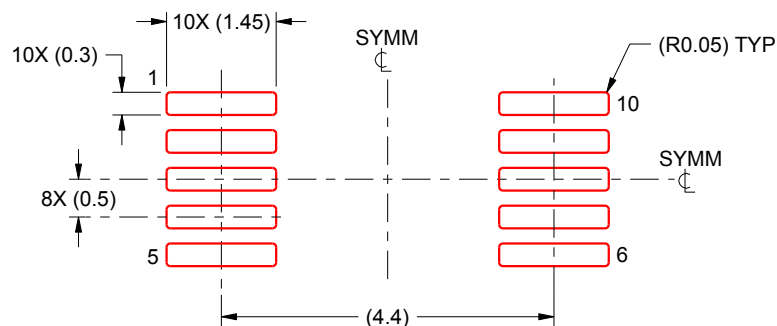
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DGS0010A

VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:10X

4221984/A 05/2015

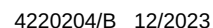
NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.



TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



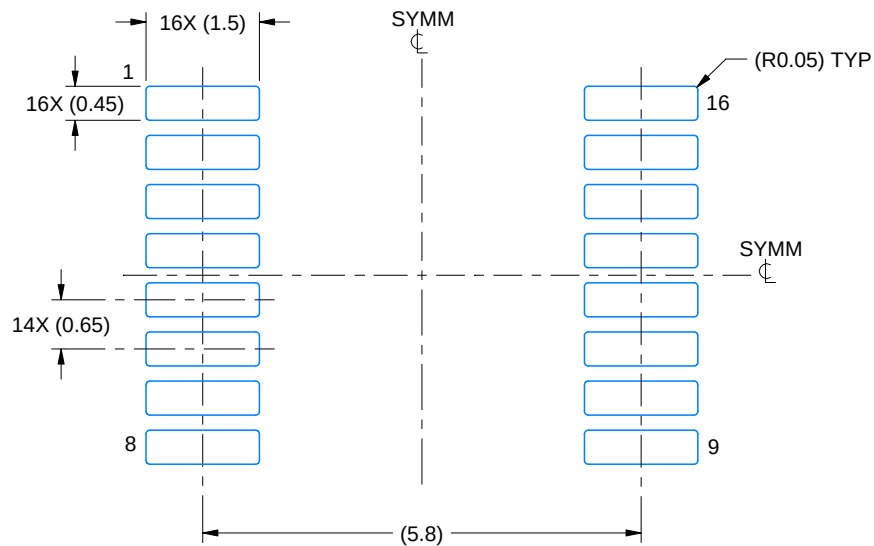
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

EXAMPLE BOARD LAYOUT

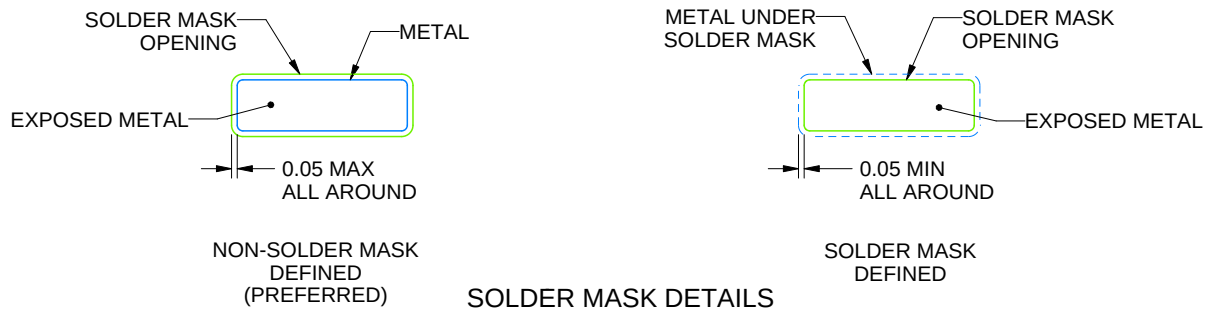
PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X



4220204/B 12/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

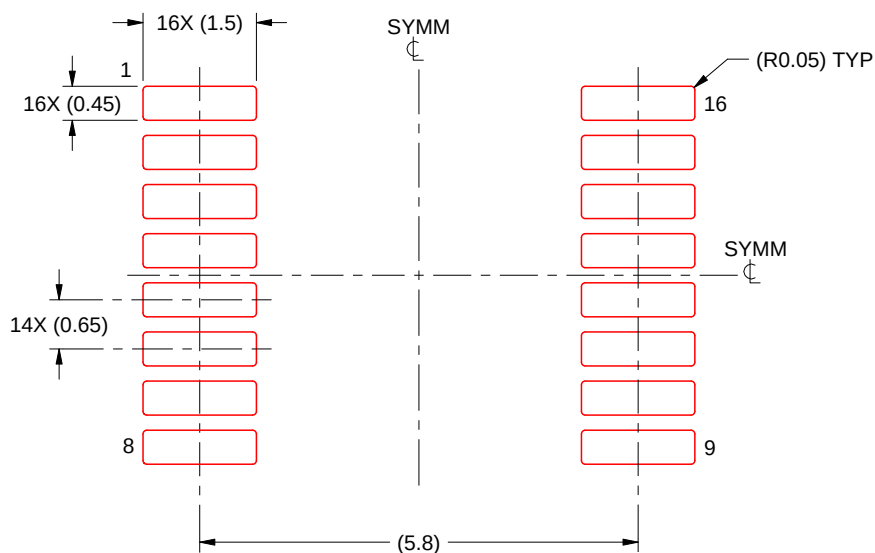
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220204/B 12/2023

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.



PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT

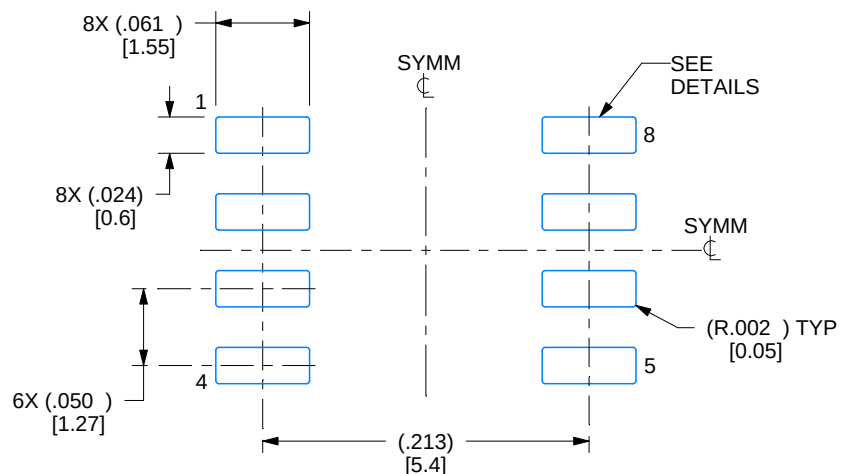


1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

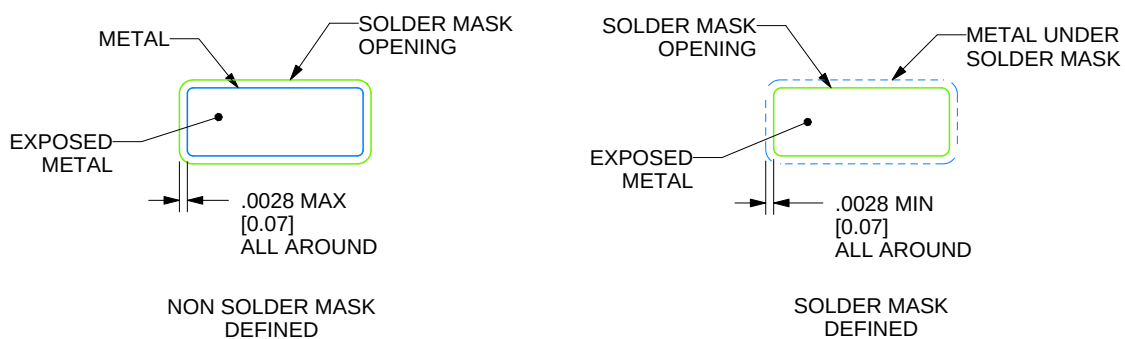
D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:8X



SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

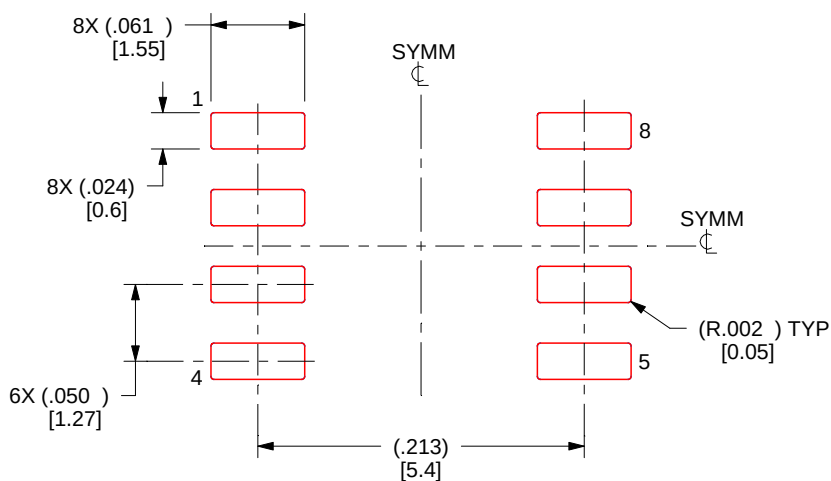
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

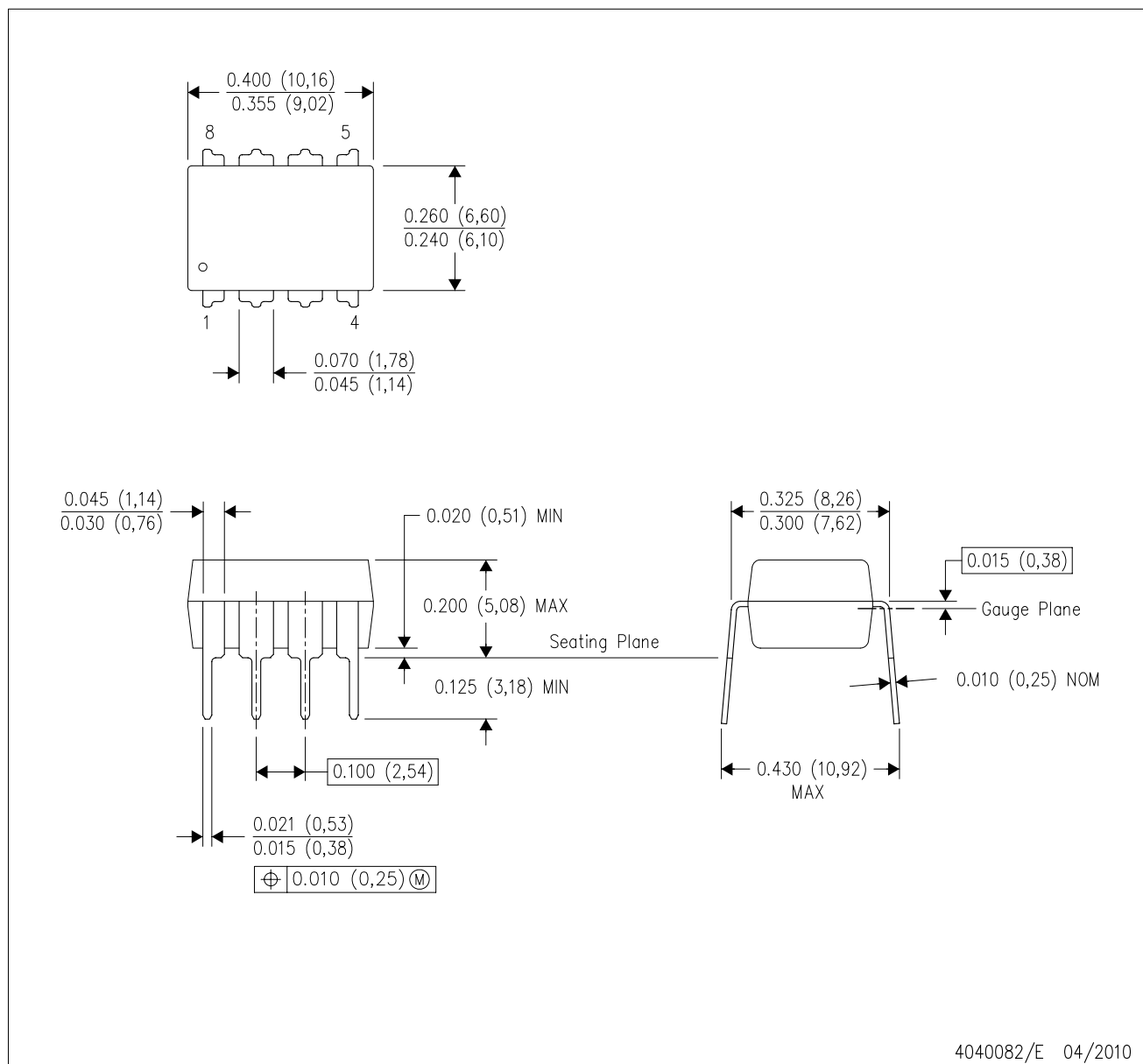
4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE

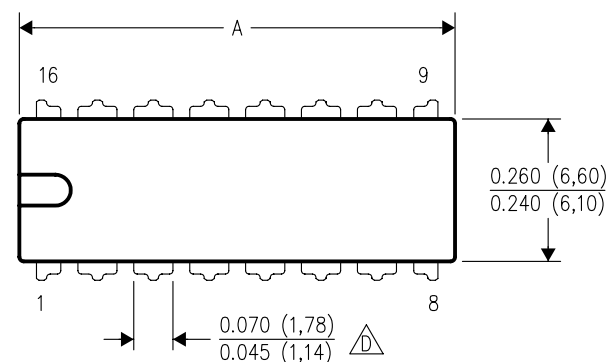


- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. Falls within JEDEC MS-001 variation BA.

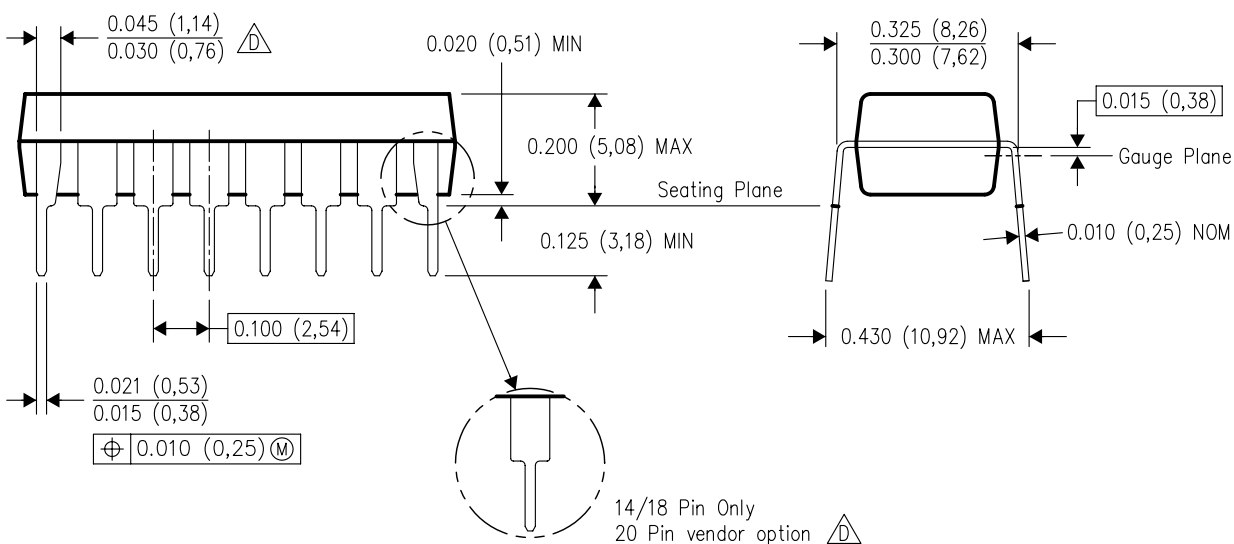
N (R-PDIP-T**)

16 PINS SHOWN

PLASTIC DUAL-IN-LINE PACKAGE



PINS ** DIM	14	16	18	20
A MAX	0.775 (19,69)	0.775 (19,69)	0.920 (23,37)	1.060 (26,92)
A MIN	0.745 (18,92)	0.745 (18,92)	0.850 (21,59)	0.940 (23,88)
MS-001 VARIATION	AA	BB	AC	AD



4040049/E 12/2002

- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 -  Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
 -  The 20 pin end lead shoulder width is a vendor option, either half or full width.

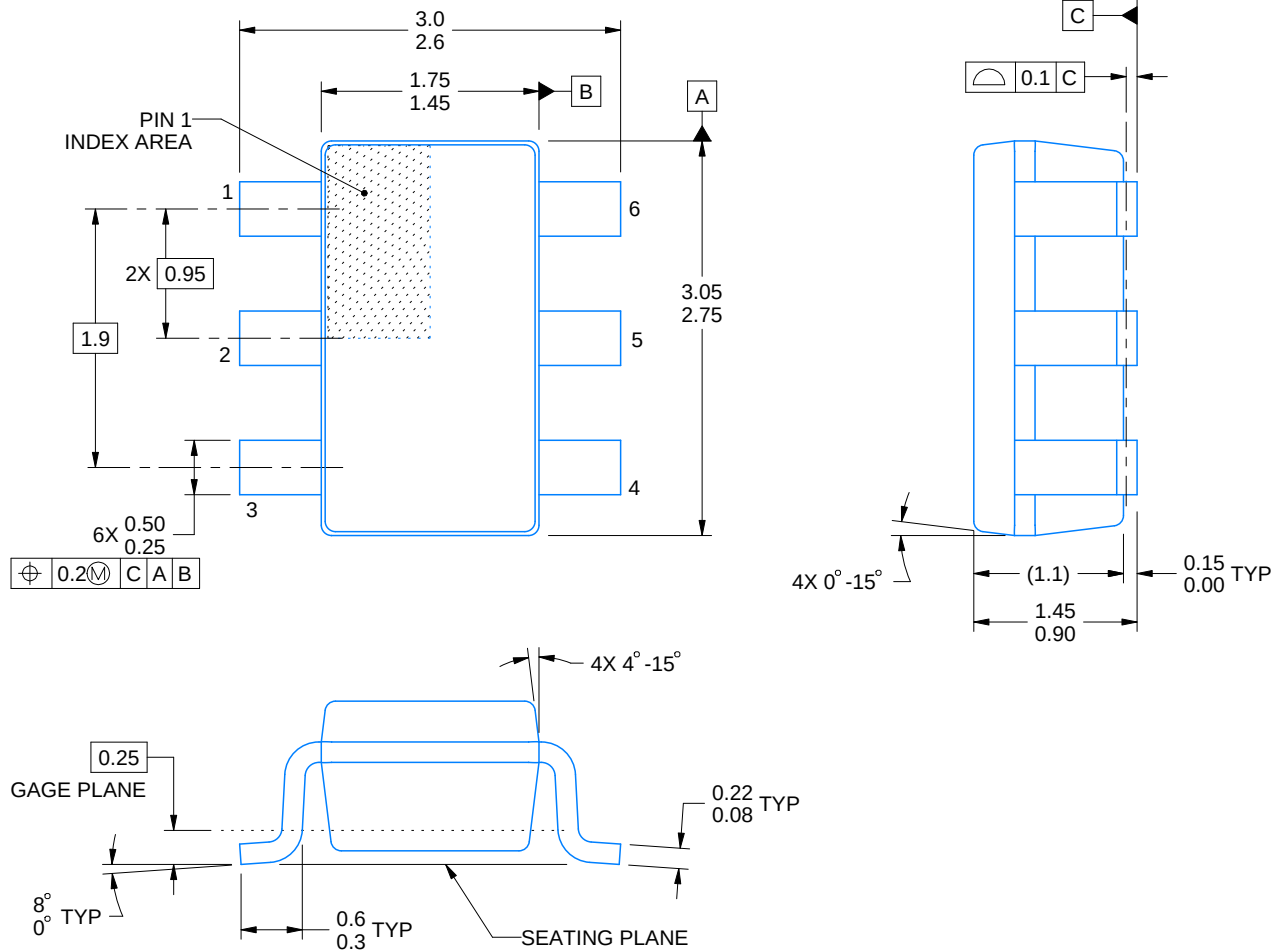


DBV0006A

PACKAGE OUTLINE

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



4214840/G 08/2024

NOTES:

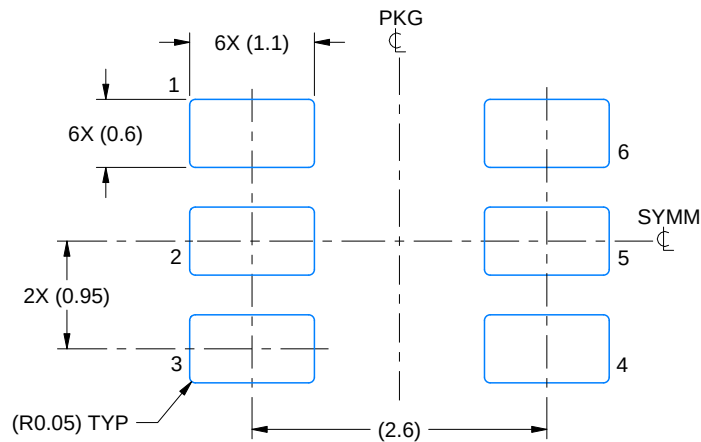
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.25 per side.
4. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
5. Reference JEDEC MO-178.

EXAMPLE BOARD LAYOUT

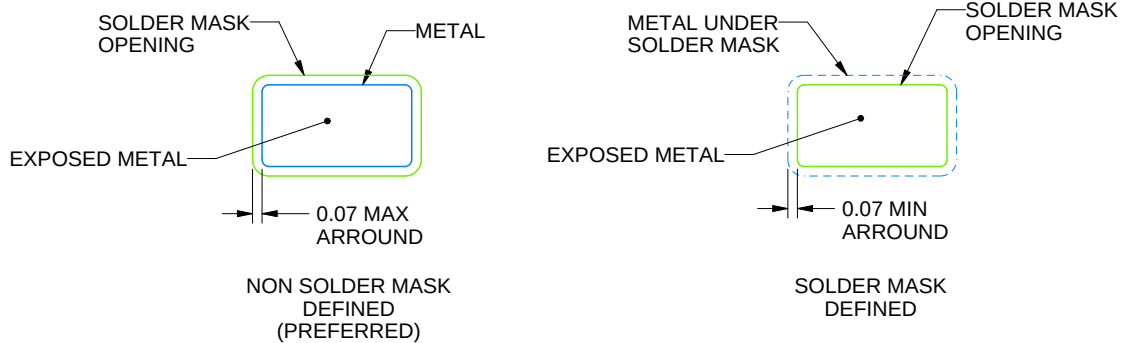
DBV0006A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X



SOLDER MASK DETAILS

4214840/G 08/2024

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

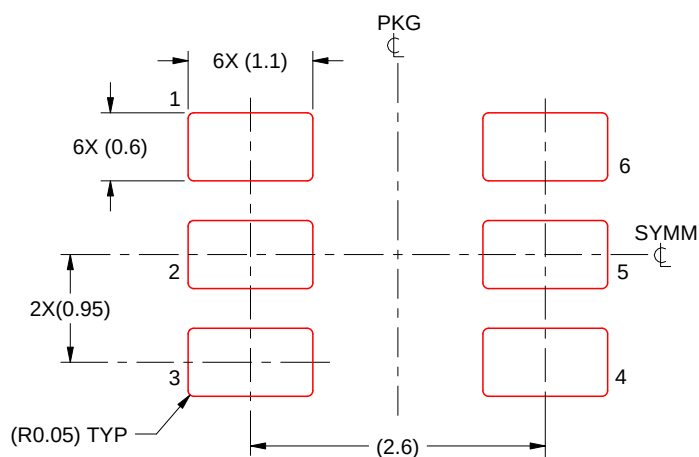
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DBV0006A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4214840/G 08/2024

NOTES: (continued)

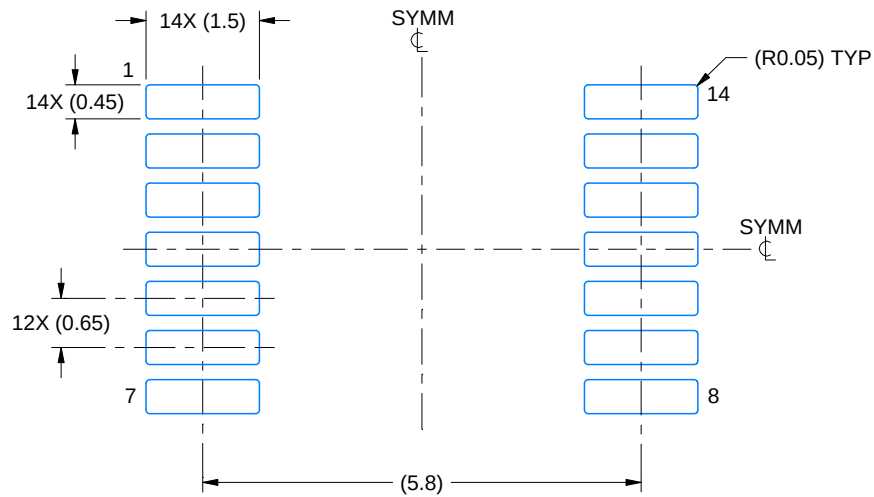
8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

EXAMPLE BOARD LAYOUT

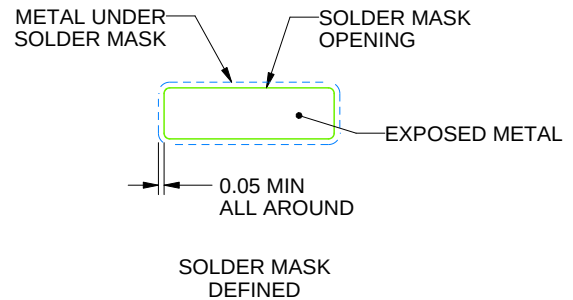
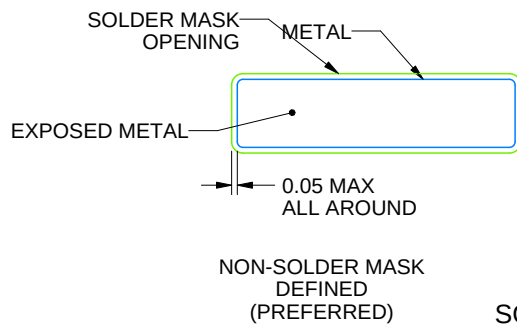
PW0014A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X



SOLDER MASK DETAILS

4220202/B 12/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

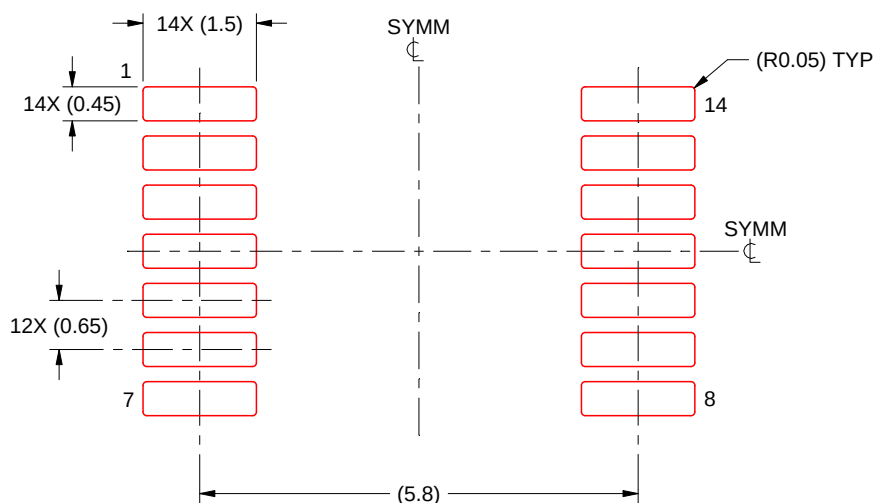
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

PW0014A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220202/B 12/2023

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

重要なお知らせと免責事項

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